AN10436 TDA8932B/33(B) Class-D audio amplifier Rev. 01 — 12 December 2007

Application note

Document information

Info	Content
Keywords	Class-D amplifier, High efficiency, Switch mode amplifier, Flat TV.
Abstract	This application note describes a stereo Switched Mode Amplifier (SMA) for audio, based on either the TDA8932B or TDA8933(B) Class-D audio amplifier device of NXP Semiconductors, which has been designed for Flat TV applications. The TDA8932B device is the high-power version that delivers an output power of 2 × 10 W _{RMS} to 2 × 25 W _{RMS} in a Single Ended (SE) configuration or 10 W _{RMS} to 50 W _{RMS} in a Bridge Tied Load (BTL) configuration. The TDA8933(B) device is the low-power version that delivers an output power of 2 × 5 W _{RMS} to 2 × 15 W _{RMS} in a SE configuration or 10 W _{RMS} to 30 W _{RMS} in a BTL configuration. This high efficiency SMA device has been designed to operate without a heat sink and has the flexibility to operate from either an asymmetrical supply or a symmetrical supply with a wide range (10 V to 36 V or ±5 V to ±18 V). The TDA8932B/33(B) device utilizes two advanced features, the Thermal Foldback (TF) and the cycle-by-cycle current limiting to avoid audio holes (interruptions) during normal operation. In addition, the TDA8932B/33(B) utilizes integrated Half Supply Voltage (HVP) buffers to simplify the design for an asymmetrical supply in the SE configuration. Control logic is integrated for a pop free transition between on/off. A SLEEP mode is incorporated to comply with the power saving regulations. An application designed around the TDA8932B/33(B) device is very robust because of the internal protection features, such as a number of voltage protections, OverCurrent Protection (OCP) and OverTemperature Protection (OTP).



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Revision history

Rev	Date	Description
01.00	20071212	First release

Contact information

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TDA8932B/33(B) Class-D audio amplifier

1. Introduction

This application note describes a reference design of a Switched Mode Amplifier (SMA) for audio, based on the TDA8932B or TDA8933(B) device of NXP Semiconductors operating from an asymmetrical supply.

The TDA8932B device and the TDA8933(B) device are pin-to-pin compatible and can be used in either a stereo SE configuration or a mono BTL configuration. The TDA8932B is the high-power version and the TDA8933(B) is the low-power version. Together they cover a wide power range per channel of 5 W_{RMS} to 50 W_{RMS} . The two versions are available in the SO32 package (TDA8932BT, TDA8933T) and the HTSSOP32 package (TDA8932BTW, TDA8933BTW). The TDA8932B/33(B) Class-D amplifier is intended for:

- Flat TV application
- Flat panel monitors
- Multimedia systems, docking stations
- Wireless speakers
- Microsystems

Distinctive features

- High efficiency Class-D audio amplifier due to a low R_{DSon} in SE configuration.
- Operates from a wide voltage range 10 V to 36 V (asymmetrical) or ±5 V to ±18 V (symmetrical).
- Maximum power capability:
 - TDA8932B is $2 \times 30 \text{ W}_{\text{RMS}}$ short time output power in 4 Ω SE without heat sink.
 - TDA8933(B) is 2 × 20 W_{RMS} short time output power in 8 Ω SE without heat sink.
- Cycle-by-cycle current limiting to avoid interruption during normal operation.
- Unique Thermal Foldback (TF) to avoid interruption during normal operation.
- Integrated Half Supply Voltage (HVP) buffers for reference and SE output capacitance (asymmetrical supply).
- Internal logic for pop free power supply on/off cycling.
- Low standby current in SLEEP mode for power saving regulations.

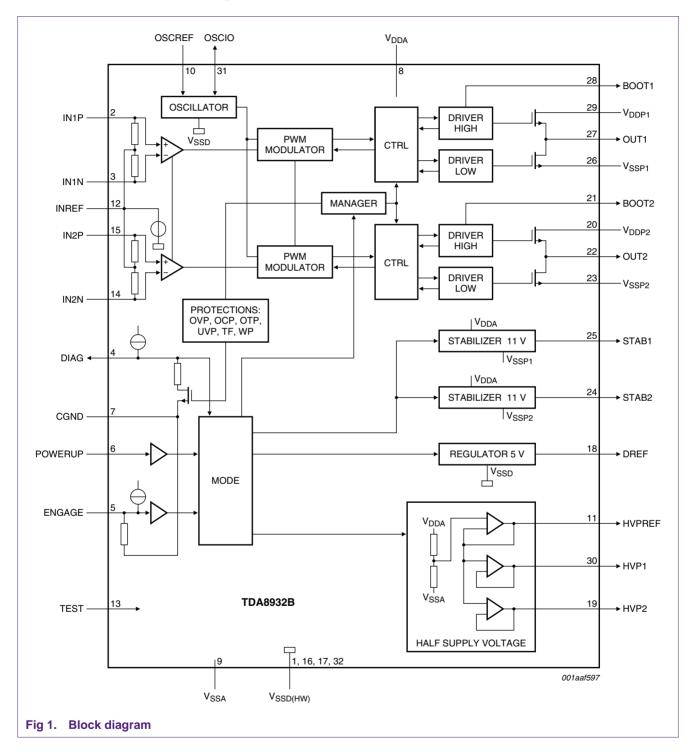
Protection features

- Window Protection (WP)
- UnderVoltage Protection (UVP)
- OverVoltage Protection (OVP)
- UnBalance Protection (UBP)
- OverCurrent Protection (OCP)
- OverTemperature Protection (OTP)
- ESD protection

These features enable an engineer to design a high performance, reliable and cost effective SMA with only a small number of external components.

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1.1 Block diagram



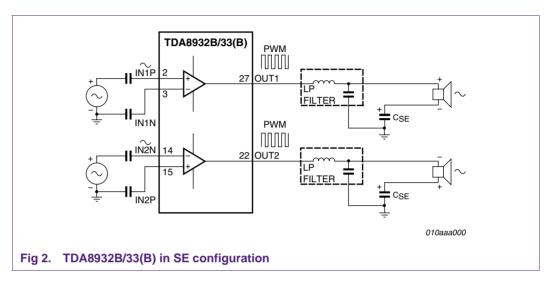
1.2 Fixed frequency pulse width modulated Class-D concept

The TDA8932B/33(B) device is a closed loop fixed frequency pulse width modulated Class-D amplifier with two differential analog inputs, each driving an independent power stage (see <u>Figure 2</u>). The power stage consists out of a low side and a high side N-channel MOSFET.

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The TDA8932B/33(B) can be configured for use in either SE or BTL. The major benefits of an SE configuration compared to a BTL configuration are cost and efficiency. This is because:

- Only one pair of power switches is required for each channel.
- Only one LP filter (inductor and film capacitor) is required for each channel.
- Only two power stages for stereo in one package, therefore no heat sink required.



An internal feedback network has a fixed closed loop gain of 30 dB in the SE configuration (36 dB in the BTL configuration).

The Pulse Width Modulation (PWM) output signal has a oscillator frequency that is fixed by either:

- · An internal oscillator when configured as master.
- An external oscillator when configured as slave.

The pulse width will be modulated according to the input signal.

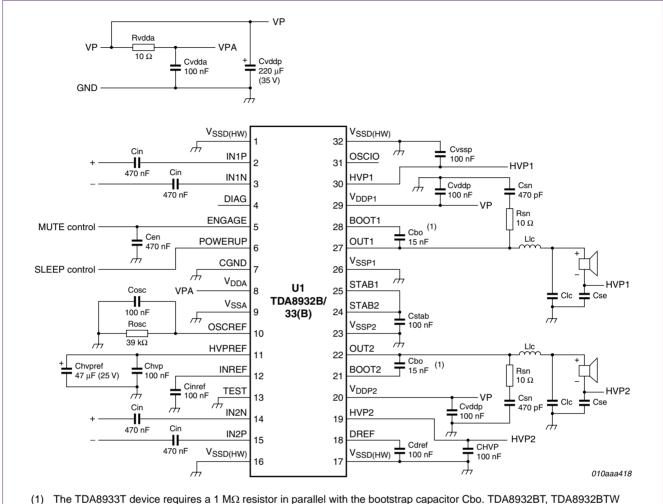
<u>Section 3</u> describes the complete application design of the TDA8932B/33(B) and includes the dimensioning of the LP output filter.

1.3 Typical application circuits (simplified)

1.3.1 Asymmetrical supply stereo SE configuration

The simplified application circuit of the TDA8932B/33(B) device when operated from an asymmetrical supply (single supply) can be seen in Figure 3. The TDA8932B/33(B) incorporates three integrated half supply voltage buffers to simplify the design for an asymmetrical supply in SE configuration. One buffer is for the reference decoupling capacitor (C_{HVPREF}) on HVPREF (pin 11) and two other buffers are for the two AC-couple capacitors (C_{SE}) in series with the speaker.

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(1) The TDA8933T device requires a 1 MΩ resistor in parallel with the bootstrap capacitor Cbo. TDA8932BT, TDA8932BTW and TDA8933BTW devices do not require a 1 MΩ resistor.

Fig 3. Simplified SE application TDA8932B/33(B) (asymmetrical supply)

1.3.2 Symmetrical supply stereo SE configuration

The TDA8932B/33(B) can operate also from a symmetrical supply (see <u>Figure 4</u>). The three half supply voltage buffers are disabled. HVPREF (Pin 11), HVP1 (pin 30) and HVP2 (pin 19) should be connected to ground when supplied from a symmetrical supply.

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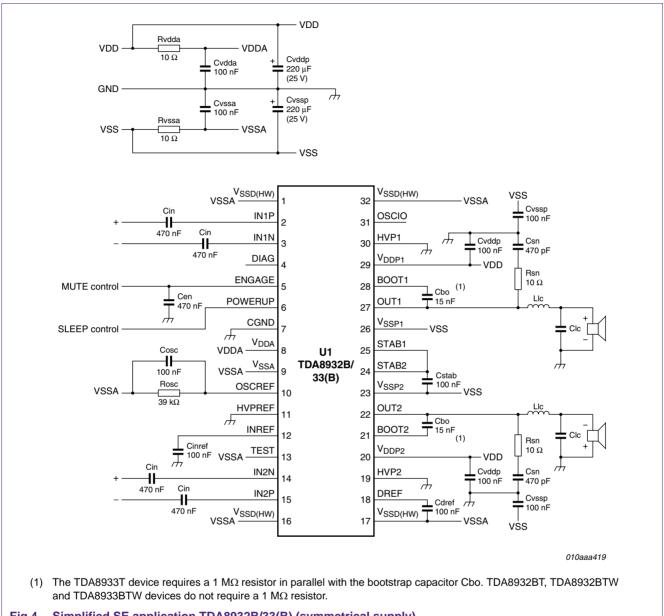


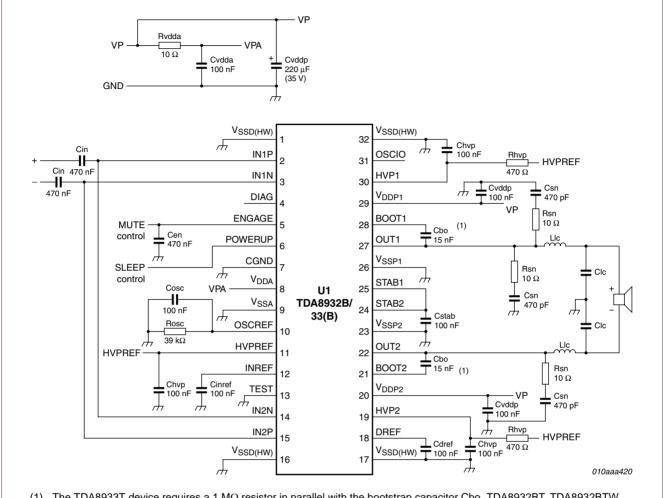
Fig 4. Simplified SE application TDA8932B/33(B) (symmetrical supply)

A symmetrical supply has some benefits compared to an asymmetrical supply. First, the power bandwidth is not limited by the size of the SE capacitor. Therefore, for a full bandwidth (20 Hz to 20 kHz) amplifier, a symmetrical supply should be considered to avoid a large value SE capacitor. Secondly, when the supply is either unregulated and/or weak (e.g., a 50 Hz / 60 Hz transformer), the output signal will not suffer from asymmetrical clipping (see Section 4.4).

1.3.3 Asymmetrical supply mono BTL configuration

The TDA8932B/33(B) can operate in BTL configuration when a high output power is required at a low supply voltage (e.g., for driving a subwoofer in a 2.1 system). See Figure 5.

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(1) The TDA8933T device requires a 1 M Ω resistor in parallel with the bootstrap capacitor Cbo. TDA8932BT, TDA8932BTW and TDA8933BTW devices do not require a 1 M Ω resistor.

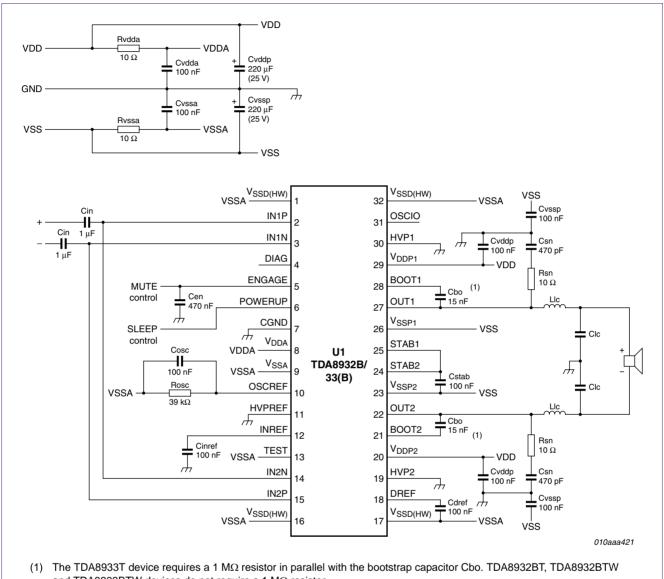
Fig 5. Simplified BTL application TDA8932B/33(B) (asymmetrical supply)

1.3.4 Symmetrical supply mono BTL configuration

The TDA8932B/33(B) can operate in BTL configuration when high output powers are required at a low supply voltage (e.g., for driving a subwoofer in a 2.1 system). See <u>Figure 6</u>.

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and TDA8933BTW devices do not require a 1 $M\Omega$ resistor.

Fig 6. Simplified BTL application TDA8932B/33(B) (symmetrical supply)

2. **Functional IC description**

This chapter briefly describes the main functionality of the TDA8932B/33(B) device and the different modes. It also describes the different features and the protections implemented in the TDA8932B/33(B). Table 3 in Section 2.8 in gives a description of each pin.

2.1 **Control inputs**

The TDA8932B/33(B) is controlled by two inputs, POWERUP (pin 6) and ENGAGE (pin 5). The POWERUP is a two-level high impedance input. The ENGAGE input has an internal pull-up current source and an internal pull-down resistor of 100 k Ω (typical). The internal pull-up current source is enabled after the power stages are

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enabled. The DIAG pin is an I/O indicating FAULT mode and it can be used to switch the amplifier in FAULT mode by means of an external pull-down to CGND. The DIAG has an internal pull-up current source.

Control voltages referenced to CGND Table 1.

Mode	V _{POWERUP} (V)	V _{ENGAGE} (V)	V _{DIAG} (V)
1) SLEEP	< 0.8	< 0.8	Does not matter
2) MUTE	> 2	< 0.8	> 2[2]
3) OPERATING	> 2	> 2.4[1]	> 2[2]
4) FAULT	> 2	Does not matter	< 0.8

^[1] ENGAGE open pin voltage is 2.8 V in OPERATING mode.

See Section 3.3 for the recommended control circuitry of the POWERUP, ENGAGE and DIAG.

Remark: Do not use an external pull-up resistor at the ENGAGE input, as it has its own internal pull-up current source.

2.1.1 **Mode description**

• SLEEP mode:

The SLEEP mode is incorporated to reduce the power consumption in system idle mode. In SLEEP mode, the internal 5 V stabilizer (DREF), the 11 V stabilizers (STAB1, STAB2) and the half supply voltage buffers (HVPREF, HVP1, HVP2) are disabled to reduce supply current consumption.

MUTE mode:

In MUTE mode, the 5 V (DREF) and the 11 V (STAB1, STAB2) stabilizers will be enabled (internal logic biased) and the half supply voltage buffers will charge respectively the reference decouple capacitor (C_{HVPRFF}) and the AC-couple capacitors (C_{SF}) in series with the speaker. The power stage is enabled (starts switching) after the SE capacitors are charged completely.

OPERATING mode:

In the OPERATING mode, the gain of the device is increased gradually to 30 dB per output stage to avoid pop noise. The complete start-up sequence will take about 500 ms in a typical SE application.

• FAULT mode:

The FAULT mode is entered when one of the internal protections is triggered (see Section 2.6) and as a consequence the DIAG (pin 4) is set to low. The internal pull-up current source of the ENGAGE pin is disabled in FAULT mode. Therefore, the external capacitor will be discharged by means of the internal pull-down resistor.

The FAULT mode can be entered also by means of an external pull-down to CGND.

Table 2 shows an overview of the internal protections.

^[2] DIAG open pin voltage is 2.5 V in MUTE and OPERATING mode.

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2.2 Half Supply Voltage (HVP) chargers

The internal HVPREF, HVP1 and HVP2 buffers will quickly charge the reference capacitor (C_{HVPREF}) and the SE capacitors (C_{SE}) before the power stage is enabled. The typical charge current of the HVP1 (pin 30) and the HVP2 (pin 19) buffers is 80 mA (dependent on the junction temperature). The charge time of the SE capacitor can be estimated as follows:

$$t = \frac{C_{SE} \cdot 0.5 \cdot (V_{DDA} - V_{SSA})}{I} \tag{1}$$

Where:

 C_{SE} = single ended capacitor (F)

V_{DDA} = analog supply voltage (V)

 V_{SSA} = negative analog supply voltage (V)

I = typical charge current (A)

Example:

Charging an SE capacitor of 1000 μ F at a supply voltage of 22 V takes about 138 ms.

Remark: The half supply voltage buffers are short circuit protected.

2.3 Pop free power supply on/off cycling

2.3.1 Supply turn-on

Internal logic will delay the operation (regardless of the control voltages) until the HVPREF, HVP1 and HVP2 buffers are settled at $\frac{1}{2}(V_{DDA} - V_{SSA})$ to avoid pop noise. For an optimum pop performance, a capacitor of 470 nF should be attached to the ENGAGE (pin 5). This will make sure the gain and therefore the offset will be increased gradually to avoid pop sound (see Figure 21).

2.3.2 Supply turn-off

Either the UnBalance Protection (UBP) or the UnderVoltage Protection (UVP) will avoid pop noise when the power supply is turned off. The power stage is disabled when either V_{DDA} drops more than 20 % (see Section 2.6.6 for more detail) or the UVP threshold level (9.5 V typical) is reached.

Remark: During power supply on/off cycling, an unwanted input signal from the audio source can still cause a pop noise. To prevent this the ENGAGE pin should be pulled down to CGND to mute any unwanted signal.

2.4 Oscillator frequency

An external resistor connected between the OSCREF (pin 10) and V_{SSA} sets the oscillator frequency of the PWM output. The oscillator frequency can be estimated with this equation:

$$f_{osc} = \frac{12.45 \cdot 10^9}{R_{osc}} \tag{2}$$

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Where:

 R_{osc} = resistor to set the oscillator frequency.

The oscillator frequency can be set between 250 kHz and 500 kHz.

Example:

The use of a 39 k Ω resistor will result in a oscillator frequency of about 320 kHz.

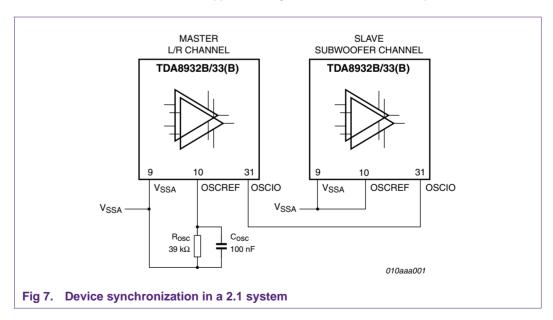
Remark: A decouple capacitor of 100 nF should be connected across R_{osc} for noise reduction.

Remark: Synchronization is recommended when two or more TDA8932B/33(B) devices are used in the same application (see Section 2.5).

2.5 Device synchronization

Synchronization is recommended to avoid possible audible beat tones from the speakers when two or more TDA8932B/33(B) devices are used in the same application. Synchronization can be achieved by connecting all OSCIOs (pin 31) together and configuring one of the devices as master, while the other TDA8932B/33(B) device is configured as slave (see Figure 7).

A device is configured as master when a resistor is connected between OSCREF (pin 10) and V_{SSA} to set the oscillator frequency. The OSCIO (pin 31) of the master is then configured as an oscillator output for synchronization. The OSCREF (pin 10) of the slave devices should be shortened to V_{SSA} to configure the OSCIO as an input.



Remark: In a 2.1 system, the SE device for the L/R channel should be configured as master.

Remark: The maximum number of slaves driven by one master is 12.

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2.6 Limiting and protection features

The TDA8932B/33(B) device utilizes two advanced limiting features, the thermal foldback and the cycle-by-cycle current limiting, to avoid audio holes (interruptions) during normal operation.

In addition to these limiting features the device has several protection features that make the TDA8932B/33(B) very robust during a fault condition. The following protections are incorporated:

- Window Protection (WP)
- UnderVoltage Protections (UVP)
- OverVoltage Protection (OVP)
- UnBalance Protection (UBP)
- OverCurrent Protection (OCP)
- OverTemperature Protection (OTP)

When one of the above protections is triggered, the device will enter the FAULT mode and the power stage is disabled immediately (floating). Furthermore, an internal timer of about 100 ms is started and the DIAG (pin 4), referenced to CGND, is set low for the first 50 ms of the timer to indicate this protection status (FAULT mode). In addition the internal pull-up current of the ENGAGE pin is disabled in the FAULT mode, so the external capacitor will be discharged by means of the internal pull-down resistor (100 k Ω). After about 100 ms the device will restart (self-recovering), but only when the fault condition has been resolved.

A microcontroller can use the diagnostic signal (DIAG) to, e.g., shut down either the amplifier or the power supply.

Table 2. Overview of all the limiting and protection features inside the TDA8932B/33(B)

Feature		Trigger I	evel		DIAG	Remark
		Min	Тур	Max	output	
TF	-	140 °C	-	150 °C	high	Unique thermal limiting to avoid audio holes when the junction temperature exceeds 140 °C during normal operation. (See Section 2.6.1)
Cycle-by-cycle	TDA8932B	4.0 A	5.0 A	-	high	Unique current limiting to avoid audio holes
current limiting	TDA8933(B)	2.0 A	2.3 A	-		when the current exceeds the trigger level during normal operation. (See Section 2.6.2)
WP[1]	low level	7.6 <mark>[1]</mark>	-	-	low[2]	Power stage stays floating and entering
	high level	14.4 <u>^[1]</u>	-	-		FAULT mode. (See <u>Section 2.6.3</u>)
UVP (V _{DDA} – V _{SSA})	-	8.0 V	9.5 V	10 V	low ^[2]	Power stage becomes floating entering FAULT mode. (See Section 2.6.4)
OVP (V _{DDA} – V _{SSA})	-	36 V	38.5 V	40 V	low[2]	Power stage becomes floating entering FAULT mode. (See Section 2.6.5)
UBP[3]	low level	-	17.6 V[3]	-	low[2]	Power stage becomes floating entering
	high level	-	29.3 V[3]	-		FAULT mode. (See Section 2.6.6)

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Table 2.	Overview of all the	imiting and protection featu	res inside the	e TDA8932B/33(B)continued

Feature		Trigger I	evel		DIAG	Remark
		Min	Тур	Max	output	
OCP	TDA8932B	4.0 A	5.0 A	-	low[2]	Power stage becomes floating entering
Low ohmic short across the load	TDA8933(B)	2.0 A	2.3 A	-		FAULT mode. (See <u>Section 2.6.7</u>)
OTP	-	155 °C	-	160 °C	low[2]	Power stage becomes floating entering FAULT mode. (See Section 2.6.8)

- [1] WP threshold level at V_P = 22 V. See Equation 3 and Equation 4 for the threshold level versus the supply voltage.
- [2] DIAG is active low for at least 50 ms.
- [3] UBP threshold level at V_P = 22 V. See Equation 5 and Equation 6 for the threshold level versus the supply voltage.

2.6.1 Thermal Foldback (TF)

When the junction of the TDA8932B/33(B) exceeds 140 °C, the TF will gradually reduce the gain, limiting the power dissipation. This means that the device will not switch off, but will continue to operate at a slightly lower gain, causing no audio holes (interruptions). The maximum junction temperature will not go beyond the absolute maximum temperature. Therefore, a heat sink is not required and the thermal design becomes less critical and less temperature head room requires to be taken into account since audio holes will not occur and the device will always stay within the Safe Operating Area (SOA).

2.6.2 Cycle-by-cycle current limiting

When the output current of the device exceeds either 4 A (TDA8932B) or 2 A (TDA8933(B)), the cycle-by-cycle current limitation becomes active. This means the device will not switch off, but continue to operate while limiting the current without causing audio holes (interruptions). The maximum output current will not go beyond the absolute maximum current.

Remark: When the cycle-by-cycle current limiting becomes active, it will cause distortion. See <u>Section 3.2</u> for information on how to calculate the peak output current, depending on the supply voltage and the speaker impedance.

2.6.3 Window Protection (WP)

WP checks the voltage at the PWM outputs (OUT1 pin 27 and OUT2 pin 22) before the power stage is enabled (transition from SLEEP mode to MUTE / OPERATING mode). To avoid large currents flowing, the WP is activated (power stage stays floating) in the event of a short from the PWM output to either V_{DD} or V_{SS} . The DIAG is set to low for at least 50 ms.

The PWM output voltage where the WP becomes active at an asymmetrical supply can be calculated as follows:

Low threshold level:

$$V_{O(wp)l} = \frac{11}{32} \cdot V_{DDA} \tag{3}$$

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High threshold level:

$$V_{O(wp)h} = \frac{21}{32} \cdot V_{DDA} \tag{4}$$

Where:

 $V_{O(wp)}$ = window protection output voltage (low or high). Referenced to V_{SSA} (V).

 V_{DDA} = analog supply voltage (V).

The TDA8932B/33(B) will recover when the output voltage at OUT1 and OUT2 is within $(21/32) V_{DDA} > V_0 > (11/32) V_{DDA}$.

2.6.4 UnderVoltage Protection (UVP)

The TDA8932B/33(B) requires a minimum supply voltage for proper operation. When the supply voltage drops below the UVP threshold level of 9.5 V (typical $V_{DDA} - V_{SSA}$), the power stage becomes floating and the DIAG is set low for at least 50 ms.

2.6.5 OverVoltage Protection (OVP)

An OVP is incorporated because an SE Class-D amplifier is able to increase the supply voltage when it is driven at low audio frequencies. This phenomenon is better known as "supply pumping" (see also Section 4.3). The OVP prevents that supply pumping exceeds the absolute maximum supply voltage rating of the TDA8932B/33(B). This is a protection against self-destruction. The OVP threshold level is an internal fixed level at 38.5 V (typical $V_{DDA} - V_{SSA}$). Beyond this OVP threshold level the power stage will become floating and the DIAG is set low for at least 50 ms.

Remark: The OVP will neither prevent nor limit an overvoltage caused by the power supply.

2.6.6 UnBalance Protection (UBP)

The UBP senses the supply voltage unbalance between the analog supply voltages V_{DDA} and V_{SSA} with respect to the HVPREF voltage at pin 11. The UBP is triggered when the unbalance exceeds a certain level to avoid improper biasing resulting in e.g. pop. The DIAG is set low and remains low for at least 50 ms.

The supply voltage where the UBP becomes active with an asymmetrical supply can be estimated as follows:

Low threshold level:

$$V_{P(ubp)l} = \frac{8}{5} \cdot V_{HVPREF} \tag{5}$$

High threshold level:

$$V_{P(ubp)h} = \frac{8}{3} \cdot V_{HVPREF} \tag{6}$$

Where:

 $V_{P(ubp)}$ = unbalance protection supply voltage (low and high). V_{DDA} (pin 8) referenced to V_{SSA} (V).

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V_{HVPREF} = half supply voltage reference (pin 11) referenced to V_{SSA} (V)

The TDA8932B/33(B) will recover when the supply voltage is within (8/5) $V_{HVPREF} > V_P > (8/3) V_{HVPREF}$.

The supply voltage at which the UBP becomes active with a symmetrical supply can be estimated as follows:

Low threshold level:

$$V_{DDA(ubp)l} = \frac{3}{5} \cdot |V_{SSA}| \tag{7}$$

High threshold level:

$$V_{DDA(ubp)h} = \frac{5}{3} \cdot |V_{SSA}| \tag{8}$$

Where:

 $V_{DDA(ubp)}$ = unbalance protection analog supply voltage. V_{DDA} (pin 8) referenced to V_{HVPREF} (V), HVPREF is connected to GND.

 V_{SSA} = negative analog supply voltage (pin 9) referenced to V_{HVPREF} (V)

Example asymmetrical supply (use Equation 5 and Equation 6):

At a supply voltage of 22 V, the voltage on HVPREF is equal to $V_{HVPREF} = 11 \text{ V}$. The HVPREF voltage is buffered so the level will change only very slowly. When the supply voltage drops quickly (dV/dt > 4 V/s), the UBP is triggered below 17.6 V. When the supply voltage increases quickly, the UBP is triggered above 29.3 V.

Remark: With either an unregulated or a weak power supply, it might happen that this UBP is triggered, e.g., because of a voltage drop during a transient from no load to full load condition. See Section 4.4 for more detail.

2.6.7 OverCurrent Protection (OCP)

The OCP is activated only in a fault condition when the current exceeds 4 A (TDA8932B) or 2 A (TDA8933(B)) because of either a low ohmic short across the load or a low ohmic short from the demodulated output (after the inductor) to either V_{SS} or V_{DD} . The DIAG is set low for 50 ms and the internal timer of 100 ms is started. The timer or the WP will keep the power stage disabled for at least 100 ms. As long as the short remains across the load, this cycle will repeat. The average power dissipation in the TDA8932B/33(B) will be low because the short circuit current will flow only during a very small part of the timer cycle of 100 ms.

When the current exceeds 4 A (TDA8932B) or 2 A (TDA8933(B)) during normal operation, only the cycle-by-cycle current limiting is active without causing any audio holes (interruptions). See also Section 2.6.2.

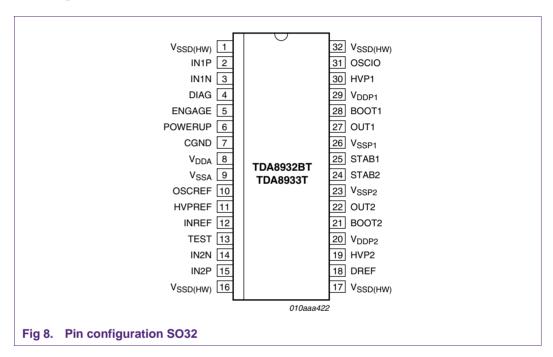
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2.6.8 OverTemperature Protection (OTP)

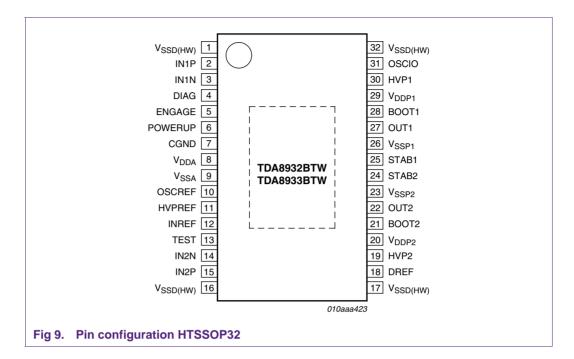
The OTP is activated only in a fault condition when the junction temperature exceeds $155\,^{\circ}\text{C}$ (typical) e.g. during a short across the SE capacitor. The DIAG output is set low for at least 50 ms and an internal timer of 100 ms is started. The timer will keep the power stage disabled for at least 100 ms.

When the junction temperature exceeds 140 °C during normal operation, the thermal foldback is active without causing any audio holes (interruptions). See also Section 2.6.1.

2.7 Pinning information



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2.8 Pin description

Table 3. Pin description

Symbol	Pin	Description
V _{SSD(HW)}	1, 16, 17, 32	Negative digital supply voltage and handle wafer connection (heat spreader). With an asymmetrical supply, the $V_{SSD(HW)}$ is connected to the supply ground. With a symmetrical supply, the $V_{SSD(HW)}$ is connected to the negative supply line, V_{SSA} .
IN1P	2	Positive audio input for power stage 1.
IN1N	3	Negative audio input for power stage1.
DIAG	4	Input/output to indicate the FAULT mode. DIAG has an internal pull-up and should left floating when unused.
ENGAGE	5	Input with internal pull-up to switch between MUTE mode and OPERATING mode.
POWERUP	6	Input to switch between SLEEP mode and MUTE mode.
CGND	7	Control ground, reference for POWERUP, ENGAGE and DIAG. This CGND is connected to the supply ground.
V_{DDA}	8	Positive analog supply voltage.
V _{SSA}	9	Negative analog supply voltage.
OSCREF	10	Input to set the frequency for the internal oscillator (master configuration). In slave configuration this pin should be connected to $V_{\rm SSA}$.
HVPREF	11	Decoupling of the internal half supply voltage reference (asymmetrical supply). With a symmetrical supply, this pin should be connected to the CGND (supply ground).
INREF	12	Decoupling for the input reference voltage.
TEST	13	Test signal input for testing purpose only (leave floating or connect to V _{SSA}).
IN2N	14	Negative audio input for power stage 2.
IN2P	15	Positive audio input for power stage 2.
DREF	18	Decoupling of the internal 5 V regulator.

TDA8932B/33(B) Class-D audio amplifier

Table 3. Pin description

Symbol	Pin	Description
HVP2	19	Half supply voltage buffer for the SE capacitor of output 2 (asymmetrical supply). With a symmetrical supply, this pin should be connected to the CGND (supply ground).
V_{DDP2}	20	Positive supply voltage for the power stage 2.
BOOT2	21	Bootstrap for the high-side driver, power stage 2.
OUT2	22	PWM output, power stage 2.
V _{SSP2}	23	Negative supply voltage for the power stage 2.
STAB2	24	Decoupling of the internal 11 V regulator for power stage 2.
STAB1	25	Decoupling of the internal 11 V regulator for power stage 1.
V _{SSP1}	26	Negative supply voltage for the power stage 1.
OUT1	27	PWM output, power stage 1.
BOOT1	28	Bootstrap for the high-side driver, channel 1.
V _{DDP1}	29	Positive supply voltage for the power stage 1.
HVP1	30	Half supply voltage buffer for the SE capacitor of output 1 (asymmetrical supply). With a symmetrical supply, this pin should be connected to the CGND (supply ground).
OSCIO	31	Oscillator input in the slave configuration or the oscillator output in the master configuration.
Exposed die pad		Exposed die pad applicable to HTSSOP32 package only. The exposed die pad should be connected to $V_{\text{SSD(HW)}}$.

3. Design 2 x 5 W - 25 W audio amplifier (asymmetrical supply)

This chapter describes a stereo amplifier reference design that is based on the TDA8932BT or the TDA8933(B)T device of NXP Semiconductors (see the schematic Section 3.10). This low-cost stereo Single Ended (SE) amplifier design operates with an asymmetrical supply (10 V to 36 V). The TDA8932BT and the TDA8933(B)T devices are pin-to-pin compatible.

The reference PCB, when mounted with TDA8932BT (high-power version), can deliver a continuous time output power of 2 \times 15 W_{RMS} into 4 Ω (V_P = 22 V) without a heat sink. The maximum short time output power is equal to 2 \times 25 W_{RMS} into 4 Ω (V_P = 29 V).

The reference PCB, when mounted with TDA8933(B)T (low-power version), can deliver a continuous time output power of 2 \times 15 W_{RMS} into 8 Ω (V_P = 31 V) without a heat sink. The maximum short time output power is equal to 2 \times 18 W_{RMS} into 8 Ω (V_P = 34 V).

This chapter shows the most important equations that can be used as a guideline for any design based on the TDA8932B/33(B).

3.1 Output power estimation

The output power for the SE and the BTL configuration, just before clipping, can be estimated through the use of these equations:

SE:
$$P_{o(0.5\%)} = \frac{\left(\left(\frac{R_L}{R_L + R_{DSon} + R_s + R_{ESR}}\right) \cdot (I - t_{W(min)} \cdot f_{osc}) \cdot V_P\right)^2}{8 \cdot R_L}$$
(9)

TDA8932B/33(B) Class-D audio amplifier

BTL:
$$P_{o(0.5\%)} = \frac{\left(\left(\frac{R_L}{R_L + 2 \cdot (R_{DSon} + R_s)}\right) \cdot (I - t_{W(min)} \cdot f_{osc}) \cdot V_P\right)^2}{2 \cdot R_I}$$
(10)

Where:

 V_P = supply voltage (V) ($V_{DDP} - V_{SSP}$)

 R_{I} = load impedance (Ω)

 R_{DSon} = on-resistance power switch (Ω)

 R_s = series resistance output inductor (Ω)

 R_{ESR} = equivalent series resistance of SE capacitance (Ω)

 $t_{W(min)}$ = minimum pulse width (s) (80 ns typical)

 f_{OSC} = oscillator frequency (Hz) (320 kHz typical R7 = 39 k Ω)

Remark: Equation 9 and Equation 10 are valid only when:

Peak output current \leq 4 A for TDA8932B (see Section 3.2).

Peak output current ≤ 2 A for TDA8933(B).

The output power at 10 % THD can be estimated as follows:

$$P_{o(10\%)} = 1.25 \cdot P_{o(0.5\%)} \tag{11}$$

3.1.1 TDA8932B output power estimation

<u>Figure 10</u>, <u>Figure 11</u>, <u>Figure 12</u>, and <u>Figure 13</u> show the estimated output power for the TDA8932B at THD = 0.5 % and THD = 10 % as a function of the supply voltage for SE and BTL for different load impedances.

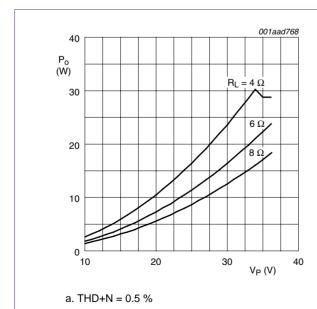
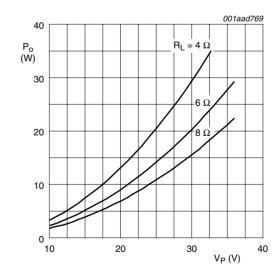


Fig 10. SE output power as a function of supply voltage

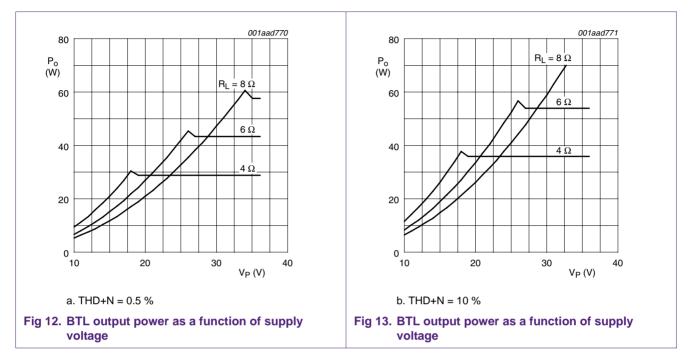


b. THD+N = 10 %

Fig 11. SE output power as a function of supply voltage

TDA8932B/33(B) Class-D audio amplifier

Remark: Figure 10 and Figure 11 are calculated with R_{DSon} = 0.15 Ω (at T_j = 25 °C), R_s = 0.05 Ω , R_{ESR} = 0.05 Ω and $I_{O(ocp)}$ = 4.0 A (minimum).



Remark: Figure 12 and Figure 13 are calculated with R_{DSon} = 0.15 Ω (at T_j = 25 °C), R_s = 0.05 Ω and $I_{O(ocp)}$ = 4.0 A (minimum).

The horizontal parts in the figures indicate the region where current limiting becomes active, when a level of 4.0 A (minimum) is taken into account. It is recommended to avoid these regions because current limiting will cause unwanted distortion (see Section 3.2).

3.1.2 TDA8933(B) output power estimation

<u>Figure 14</u>, <u>Figure 15</u>, <u>Figure 16</u>, and <u>Figure 17</u> show the estimated output power for the TDA8933(B) at THD = 0.5 % and THD = 10 % as a function of supply voltage for SE and BTL for different load impedances.

TDA8932B/33(B) Class-D audio amplifier

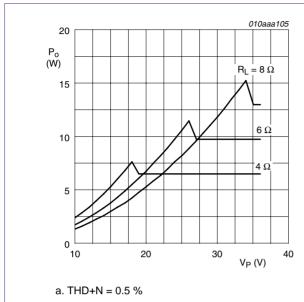
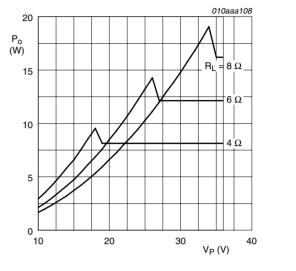


Fig 14. TDA8933(B): SE output power as a function of supply voltage



b. THD+N = 10 %

Fig 15. TDA8933(B): SE output power as a function of supply voltage

Remark: Figure 14 and Figure 15 are calculated with R_{DSon} = 0.39 Ω (at T_j = 25 °C), R_s = 0.05 Ω , R_{ESR} = 0.05 Ω and $I_{O(OCD)}$ = 2.0 A (minimum).

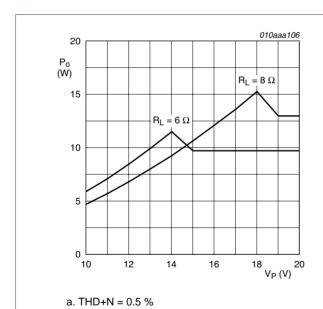
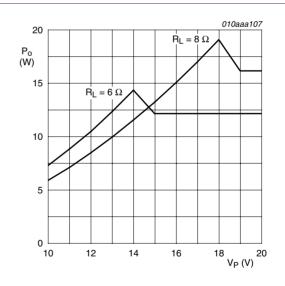


Fig 16. TDA8933(B): BTL output power as a function of supply voltage



b. THD+N = 10 %

Fig 17. TDA8933(B): BTL output power as a function of supply voltage

Remark: Figure 16 and Figure 17 are calculated with R_{DSon} = 0.39 Ω (at T_j = 25 °C), R_s = 0.05 Ω and $I_{O(ocp)}$ = 2.0 A (minimum).

The horizontal parts in the figures indicate the region where current limiting becomes active when a level of 2.0 A (minimum) is taken into account. It is recommended to avoid these regions because current limiting will cause unwanted distortion (see <u>Section 3.2</u>).

TDA8932B/33(B) Class-D audio amplifier

3.2 Peak output current estimation

The most important benefit of cycle-by-cycle current limiting is the loss of audio holes without requiring a lot of head room towards the maximum peak output current of the TDA8932B/33(B). The peak output current is limited internally above:

- 4 A minimum for the TDA8932B.
- 2 A minimum for the TDA8933(B).

During normal operation, the output current should not exceed the threshold level of $I_{O(ocp)} = 4$ A minimum (TDA8932B) or $I_{O(ocp)} = 2$ A minimum (TDA8933(B)) because it will cause distortion. The peak output current in either SE or BTL can be estimated through the use of these equations:

SE:
$$I_{O(peak)} \le \frac{0.5 \cdot V_P}{R_L + R_{DSon} + R_s + R_{ESR}}$$
 (12)

BTL:
$$I_{O(peak)} \le \frac{V_p}{R_I + 2 \cdot (R_{DSon} + R_s)}$$
 (13)

Where:

 $V_P = \text{supply voltage (V) } (V_{DDP} - V_{SSP})$

 R_L = load impedance (Ω)

 R_{DSon} = on-resistance power switch (Ω)

 R_s = series resistance output inductor (Ω)

 R_{ESR} = equivalent series resistance of SE capacitance (Ω)

Example TDA8932B ($I_{O(ocp)} = 4$ A minimum):

A 4 Ω speaker in the SE configuration can be used until a supply voltage of 33 V (approx.) without running into current limiting.

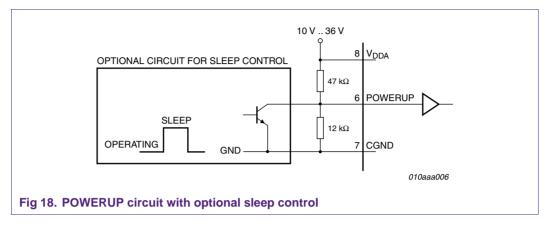
A 4 Ω speaker in the BTL configuration can be used until a supply voltage of 17.5 V (approx.) without running into current limiting.

3.3 Control circuit

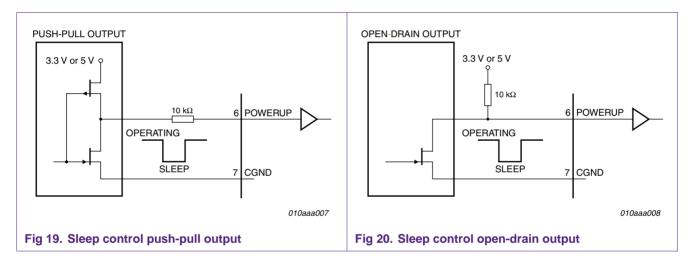
The recommended POWERUP circuit is a resistor divider between the supply voltage and CGND of the amplifier. Optionally a transistor can be used to enter SLEEP mode to reduce the power consumption in e.g., system idle mode.

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TDA8932B/33(B) Class-D audio amplifier

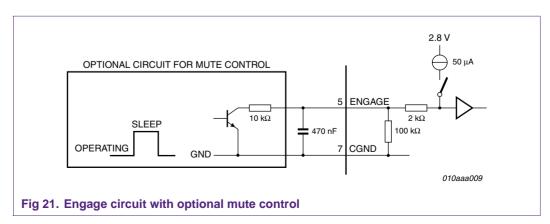


<u>Figure 19</u> and <u>Figure 20</u> show two alternative POWERUP circuits to control SLEEP mode from a 3.3 V or 5 V logic supply by means of a micro controller.



Remark: Pull-up resistor should be $\geq 1 \text{ k}\Omega$.

An external capacitor of 470 nF is recommended at the ENGAGE pin. The switch in series with the internal pull-up current source will be closed after the power stage is enabled and finally the external capacitor will "softly" engage the amplifier. Softly means that the gain is gradually increased depending on the capacitor value (dV/dt) attached to the ENGAGE pin avoiding pop noise due to DC offset.



TDA8932B/33(B) Class-D audio amplifier

Remark: Do not use an external pull-up resistor at the ENGAGE input.

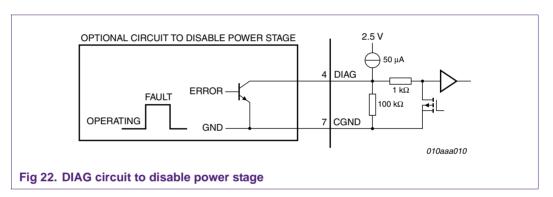
Remark: For a quick enable of the MUTE mode it is recommended to short circuit the 10 k series resistor.

The DIAG pin can be used to:

- Read out the status of respectively OPERATING mode or FAULT mode.
- Quickly disable the power stage in case of fault conditions at set level.

The internal pull-up current is limited (approx. 50 μ A) therefore the maximum resistive load (referenced to CGND) is 47 k Ω . DIAG open pin voltage is 2.8 V (typ).

The absolute maximum sink current of the DIAG pin should be limited to 5 mA (internal pull-down resistance $R_{pd}\approx 1~k\Omega$ when set low).

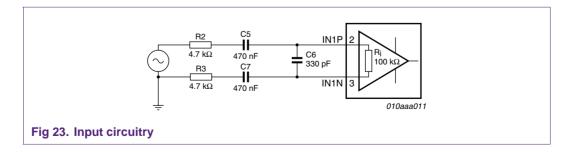


Remark: The DIAG should be left floating when unused.

3.4 Analog audio input

The input signal is applied to the differential input of the TDA8932B/33(B) by means of AC-couple capacitors (see <u>Figure 23</u>). AC-couple capacitors are required for DC-blocking because the inputs (IN1P, IN1N, IN2P and IN2N) are biased at a voltage level of approximately +2.2 V (with respect to VSS) when operating from an asymmetrical supply. At symmetrical supply, the inputs are biased at a voltage level of approximately –2.2 V (with respect to HVPREF). The bias voltage is equal to the INREF voltage (pin 12).

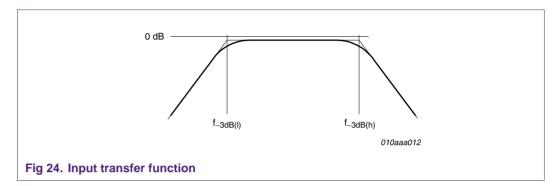
Remark: The input should be grounded close to the audio source (not at the amplifier side) to avoid a common ground with the power supply ground.



TDA8932B/33(B) Class-D audio amplifier

3.4.1 Input impedance

The input impedance of the TDA832B/33(B) device is equal to R_i = 100 k Ω . A low pass RC filter (R2, R3 and C6) is applied to reduce the sensitivity for out-of-band disturbances.



The closed loop voltage gain at 1 kHz is equal to:

$$G_{v(cl)} = 20log\left(\frac{R_i}{R2 + R3 + R_i}\right) \tag{14}$$

The cut-off frequency of the low-pass filter is equal to:

$$f_{-3dB(h)} = \frac{1}{2\pi \cdot \frac{(R2 + R3) \cdot R_i}{R2 + R3 + R_i} \cdot C6}$$
 (15)

The AC couple capacitors form a high-pass filter, with the total input impedance $(R2 + R3 + R_i)$. The cut-off frequency of the high-pass filter is equal to:

$$f_{-3dB(l)} = \frac{1}{2\pi \cdot (R2 + R3 + R_i) \cdot \left(\frac{C5 \cdot C7}{C5 \cdot C7}\right)}$$
(16)

Example:

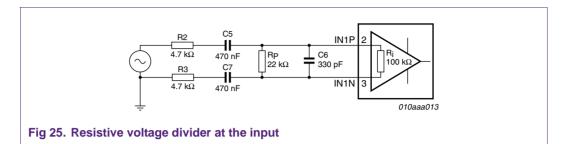
Substituting R2, R3 = 4.7 k Ω and the AC-couple capacitors of C5, C7 = 470 nF in Equation 16 results in a cut-off frequency of 6 Hz, well below 20 Hz.

Substituting R2, R3 = 4.7 k Ω and C6 = 330 pF in Equation 15 results in a cut-off frequency of 56 kHz, well above 20 kHz.

3.4.2 Gain reduction

The gain of the TDA8932B/33(B) is fixed internally at 30 dB for SE configuration (or 36 dB BTL configuration). The gain can be reduced by a resistive voltage divider at the input (see Figure 25).

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The closed-loop voltage gain $G_{v(cl)}$ when applying a resistive divider can be calculated through the use of this equation:

$$G_{v(tot)} = G_{v(cl)} + 20log\left(\frac{R_{EQ}}{R_{EQ} + (R2 + R3)}\right)$$
 (17)

$$R_{EQ} = \frac{R_p \cdot R_i}{R_p + R_i} \tag{18}$$

Where:

 R_{EQ} = equivalent resistance (Ω)

 R_p = parallel resistor (Ω)

 $R_i = 100 \text{ k}\Omega$ internal input resistance (Ω)

R2, R3 = series resistors (Ω)

 $G_{V(cl)}$ = closed-loop voltage gain 30 dB for SE and 36 dB for BTL (dB)

Example:

Substituting R2 = R3 = 4.7 k Ω and R_P = 22 k Ω in Equation 17 and Equation 18 results in a gain of $G_{v(tot)}$ = 26.3 dB.

Remark: Applying a parallel resistance to reduce the gain will affect the cut-off frequencies of the input circuitry. It is required to compensate for this when requiring a 20 Hz to 20 kHz bandwidth.

3.4.3 Reference decoupling (HVPREF)

The HVPREF voltage (equal to $\frac{1}{2}(V_{DDA}-V_{SSA})$) is the reference for the output. The HVPREF is created internally by a resistor divider (2 × 90 k Ω) located between V_{DDA} and V_{SSA} . Proper decoupling with 47 μ F and 100 nF is necessary to assure a good SVRR in the SE configuration. For the BTL configuration, there is a requirement only for a 100 nF capacitor since any ripple on the HVPREF is common for both output stages.

3.5 Speaker configuration and impedance

For a flat frequency response (second order Butterworth filter), it is necessary to change the low pass filter components L2 / L3 and C14 / C23 according to the speaker configuration and impedance. See Figure 35 for more information.

Table 4 shows the required component values for speaker impedances of 4 Ω , 6 Ω or 8 Ω .

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Table 4. Tiller Co	imponent values		
Configuration	Impedance (Ω)	L2 / L3 (μH)	C14 / C23 (nF)
SE	4	22	680
	6	33	470
	8	47	330
BTL	4	10	1500
	6	15	1000
	8	22	680

Table 4. Filter component values

3.5.1 Filter inductor

There are two main types of inductors:

- Air coil, current independent inductance and no saturation effect.
- Inductor with a magnetic core (ferrite or iron powder):
 - Magnetically unshielded version (pot core).
 - Magnetically shielded version (pot core or toroidal core).

An air coil is used often in HiFi audio equipment, but is not very useful in mainstream audio because of the physical size.

The major benefit of an unshielded inductor is cost. However, the magnetic stray field can cause either crosstalk issues or interference with other sensitive parts inside an audio or TV system (AM-receiver, picture interference, etc.).

The benefit of the shielded magnetic inductor is that the magnetic field is captured inside the core, reducing the magnetic stray field.

The most important parameters of an inductor are:

- DC current rating to avoid magnetic saturation, causing an increase in audio distortion.
- Linearity of the inductor, causing an increase in audio distortion (especially above 1 kHz).
- DC resistance having a direct impact on efficiency.

The DC current capability needs to be high enough to avoid magnetic saturation. High peak currents are a result of saturation because the inductor tends to acts like a short. Therefore, for a proper inductor selection it is important to consider the maximum current delivered by the amplifier, and the temperature of the inductor (higher inductor temperature will decrease the saturation level). The maximum current occurs at voltage clipping and can be calculated through the use of either Equation 12 for SE configuration or Equation 13 for BTL configuration.

Example:

For a 2 \times 15 W SE amplifier operating at 22 V the maximum output current is equal to 2.1 A (R_{DSon} = 0.15 Ω and R_s = 0.05 Ω and R_{ESR} = 0.06 Ω). Therefore, it is recommended to select an inductor that retains still at least 80 % of the nominal inductance at the maximum current of 2.1 A.

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Remark: Saturation will cause audio distortion and severe saturation might even damage the device.

The inductor types listed below are recommended, based on audio and EMC performance.

Table 5.	Recommended	inductor types
----------	-------------	----------------

Brand and type	L (μH)	I _{sat} (A)	Output power (W per channel) in R _L = 4 Ω
TOKO 16RHBP leaded,	22	4.9	25
shielded	47	3.4	
TOKO 11RHBP A7503CY	22	2.21	15
leaded, shielded	47	1.60	
TOKO DS86C	22	2.0	10
B992AS SMD, shielded	47	1.4	
Sagami 7311NA leaded,	22	3.4	25
shielded	47	2.3	
Sagami 7E08N SMD,	22	2.6	15
shielded	47	1.8	

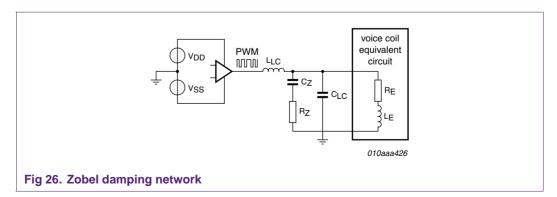
Remark: For EMC purposes, it is important that the inner layer (for a multiple layer winding) is attached to the switching output to minimize electrical stray fields. The inner layer (start of the winding) is indicated with a dot mark on the inductor. In this way the outside layer acts like an electrical shielding for the inner layer attached to the output with fast alternating voltages.

3.5.2 Filter capacitor

A film capacitor is the best choice for audio performance. However, in most cases a ceramic SMD capacitor (NPO or X7R) will also give a satisfying performance. The voltage rating of the filter capacitor should be 25 % higher than the maximum supply voltage V_P in an asymmetrical application. In a symmetrical application the voltage rating should be 25 % higher than the half the maximum supply voltage ($V_{DDP} - V_{SSP}$).

3.5.3 Zobel damping network

A zobel network is recommended in every Class-D amplifier application to damp the filter resonance (See in Figure 26 R_Z and C_Z). Filter resonance will occur due to the inductive behavior (L_E) of the speaker voice coil.



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TDA8932B/33(B) Class-D audio amplifier

This zobel damping network is quite effective for a voice coil inductance $L_E < 10 L_{LC}$. The zobel damping network will lower the resonance peak current in the filter inductor by at least 15 % to 40 % lowering the risk of unwanted inductor saturation.

Remark: Besides inductor saturation a tweeter might also benefit from a zobel network since filter resonance can overstress the tweeter.

Table 6 contains the optimum damping resistors for different capacitor values:

Table 6. Damping resistors for different capacitor values

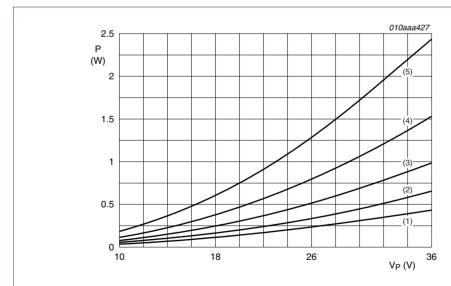
Configuration	Speaker impedance (Ω)	L _{LC} (μH)	C _{LC} (nF)	C _Z (nF)	R _Z (Ω)
	-	-	-	47	82
	-	-	-	68	56
Single ended	4	22	680	100	39
	-	-	-	150	27
	-	-	-	220	22

A minimum zobel damping network $C_Z = 47$ nF and $R_Z = 82 \Omega$ is strongly recommended.

The optimum damping resistors are equal for 6 Ω and 8 Ω speakers when using the filter component values from Table 4, which are calculated based on $f_0 = 40$ kHz.

The resistor (R₇) should be able to at least dissipate the power when driving the amplifier with a 20 kHz unclipped sine wave.

Figure 27 shows the sine wave power dissipation (20 kHz) as a function of supply voltage.



- (1) $C_Z = 47 \text{ nF} / R_Z = 82 \Omega$
- (2) $C_Z = 68 \text{ nF} / R_Z = 56 \Omega$
- (3) $C_Z = 100 \text{ nF} / R_Z = 39 \Omega$
- (4) $C_Z = 150 \text{ nF} / R_Z = 27 \Omega$
- (5) $C_Z = 220 \text{ nF} / R_Z = 22 \Omega$

Fig 27. Power dissipation as a function of supply voltage

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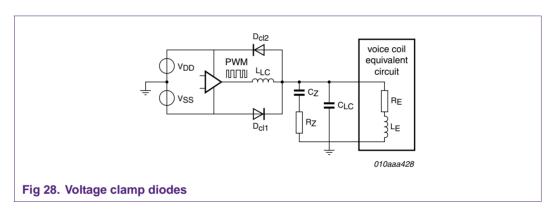
Remark: If the amplifier is driven at the resonance frequency ($f_0 = 40 \text{ kHz}$) of the filter, the power dissipation in the resistor will rise causing the resistor to overheat.

3.5.4 Voltage clamp diodes

For a voice coil inductance L_E greater than 10 times the filter inductance (L_{LC}) the effectiveness of the zobel damping network is limited and the power dissipation in the resistor grows high, requiring bulky power resistors. In general, mostly subwoofer voice coils and HIFI multi-way speakers have such a high inductance.

Remark: Applications for which the end user is able to disconnect the speaker and operate the amplifier without speaker, might also suffer from issues of robustness because of the inductor saturation.

To avoid inductor saturation in case of high inductive load or no load, it is recommended to apply voltage clamp diodes at the output to the supply rails (see Figure 28).



Relatively cheap general purpose diodes, like the 1N4001 ($V_R = 50 \text{ V}$) or the 1N4002 ($V_R = 100 \text{ V}$) can be used for this purpose. The reverse voltage of the diode should be at least 1.2 times the supply voltage and the repetitive peak current should be 1.2 times the maximum current of the amplifier.

3.6 Single ended capacitor

A single ended amplifier (Class-AB or Class-D) operating at an asymmetrical supply voltage will require an AC couple capacitor (SE capacitor) in series with the speaker. Especially for a low output power (< 25 W) it is a very cost effective solution compared to a BTL configuration. It should be noted, the SE capacitor has no major drawback on THD and audio performance in general.

The SE capacitor forms a high-pass filter with the speaker impedance. Therefore, the frequency response will roll off with 20 dB per decade below the cut-off frequency f_{-3dB} . The cut-off frequency is equal to:

$$f_{-3dB} = \frac{1}{2\pi \cdot R_L \cdot C15} \tag{19}$$

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Where:

 R_L = load impedance (Ω).

C15 (C24) = Single Ended capacitance (F) (see schematic Section 3.10).

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Table 7 shows the required SE capacitor values for a cut-off frequency of 60 Hz, 40 Hz and 20 Hz.

Table 7. **Values SE capacitor**

Impedance (Ω)	C15 / C24 (µF)				
	f _{-3dB} = 60 Hz	f _{-3dB} = 40 Hz	f _{-3dB} = 20 Hz		
4	680	1000	2200		
6	470	680	1500		
8	330	470	1000		

3.6.1 Voltage rating

The voltage rating of the SE capacitor should be at least equal to the nominal supply voltage V_P in the application. This because the voltage at the SE capacitor can be modulated heavily when the amplifier is driven at either a low frequency or during an overload (a short circuit across the load or to V_P). In these situations the peak voltage at the SE capacitor can be almost equal to the supply voltage.

3.6.2 Lifetime

The ambient temperature and the ripple current have the greatest effect on the lifetime of the aluminium electrolytic capacitors. For lifetime considerations the SE capacitance must be able to at least handle the ripple current that is equal to the load current at 1/4 rated output power. Only ¼ of the rated output power is taken into account, because it is not likely that an audio amplifier is driven continuously at rated output power over a lifetime.

The ripple current at ¼ P_{rated} is equal to:

$$I = \frac{1/2 \cdot V_P}{\sqrt{2} \cdot R_I} \cdot \frac{1}{4} \tag{20}$$

Where:

 R_1 = load impedance (Ω)

 V_P = supply voltage (V) ($V_{DDP} - V_{SSP}$)

Example:

The ripple current of an amplifier that operates at 22 V with a 4 Ω load ($P_{rated} = 15$ W) is approximately 486 mA. This ripple current can be used to determine the expected lifetime of the SE capacitor. Most general purpose electrolytic capacitors (85 °C type) are capable already of handling a 486 mA ripple current.

Both the ripple current and the voltage rating must be considered to prevent the capacitor from failing.

3.7 Bootstrap capacitor

A 15 nF SMD capacitor (NPO or X7R) is required to drive the high side N-channel MOSFET. The bootstrap capacitor is charged by means of an internal diode between the STAB1 (pin 25) and the BOOT1 (pin 28) at the moment that the low side MOSFET is on.

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The voltage across the bootstrap capacitor is equal to $V_{STAB1} - V_F$ (forward voltage drop internal diode). Therefore a voltage rating of 16 V is sufficient for the two bootstrap capacitors.

Remark: Only the TDA8933T device requires a 1 M Ω across both bootstrap capacitors for discharging when the power stage becomes floating.

3.8 Output RC snubber network

An RC snubber network (see schematic <u>Section 3.10</u>) reduces the voltage ringing at the power stage output (pin 22 and pin 27) after a voltage transition. A proper implementation of this RC snubber will improve the EMC performance (see Figure 33).

The worst case power dissipation in the snubber resistor R5 (R12) is equal to:

$$P = 1/2 \cdot C9 \cdot (V_p)^2 \cdot 2 \cdot f_{osc} \tag{21}$$

Where:

C9 (C29) = snubber capacitor (F) V_P = supply voltage (V) ($V_{DDP} - V_{SSP}$) f_{osc} = oscillator frequency (Hz)

Example:

Substituting C9 = 470 pF, V_P = 22 V and f_{osc} = 320 kHz in Equation 21, results in a power dissipation of 73 mW, requiring an 0805 SMD.

The voltage rating of the snubber capacitors (C9 and C26) should be 25 % higher than the maximum supply voltage in the application.

3.9 Layout recommendations

The PCB design of an SMA is probably the most difficult part of the design, because it might affect the audio performance, the EMC performance, the thermal performance, or even the functionality of the TDA8932B/33(B).

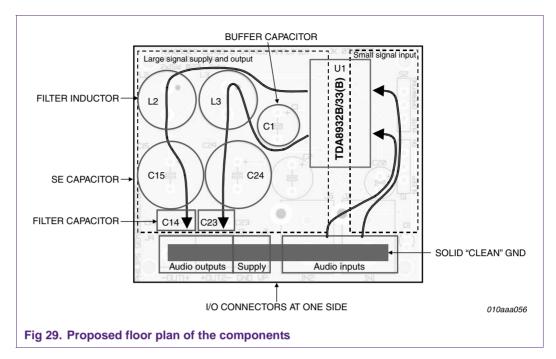
3.9.1 EMC considerations

A double-sided PCB with plated through holes and 35 μm copper is recommended, but a single layer is feasible as well.

<u>Figure 29</u> shows a proposed floor plan of the critical components that contribute to a good audio and EMC performance. The top side of this reference board is used to place the leaded components and the copper plane for thermal reasons. For more information on thermal considerations refer to <u>Section 3.9.2</u>.

The bottom side of the double-layer PCB is used to place the SMD components, including the TDA8932B/33(B) and the majority of the signal tracks (see <u>Figure 30</u> to <u>Figure 33</u>).

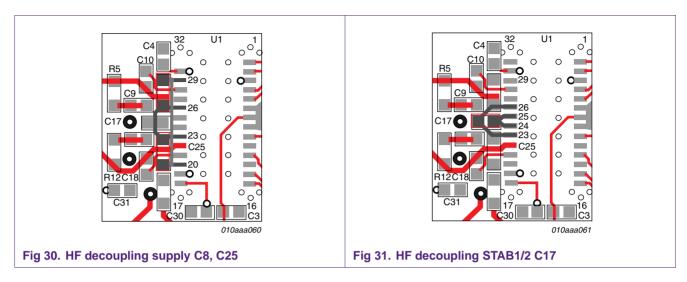
TDA8932B/33(B) Class-D audio amplifier

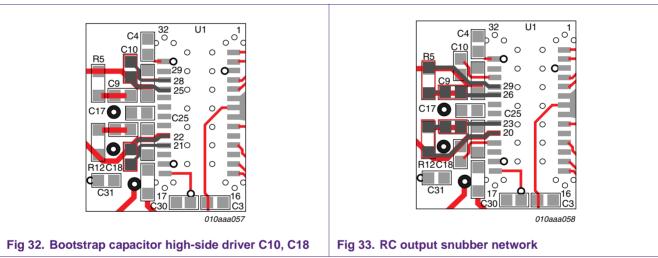


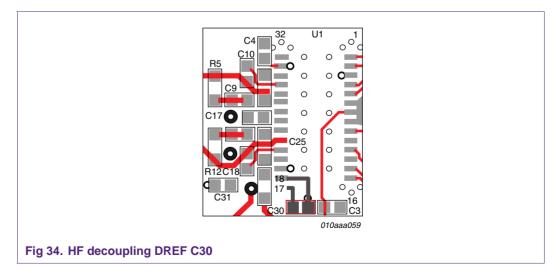
Some important notes for a proper layout are summarized below:

- Input / output connectors at one side of the PCB (solid and "clean" star GND connection).
- Supply buffer capacitor (C1) close to the IC.
- Filter inductor (L2, L3) close to the IC.
- Filter capacitor (C14, C23) close to the output connector, together with the SE capacitor (C15, C24).
- Place the High Frequency (HF) supply decoupling capacitor close to the IC (see Figure 30).
- Place the HF decoupling capacitor STAB1/2 voltage close to the IC (see Figure 31).
- Place the Bootstrap capacitor of the high-side driver close to the IC (see Figure 32).
- Place the RC output snubber network close to the IC (see Figure 33).
- Place the HF decoupling capacitor DREF voltage close to the IC (see <u>Figure 33</u>).

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Remark: SMD components are on the bottom layer, viewed from the top.

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In general:

- Minimizing the current loops that carry fast alternating currents will reduce magnetic radiation.
- Minimizing the length / size of the PWM output track (fast alternating voltages) as much as possible, will prevent capacitive coupling to the environment. Otherwise this could lead to disturbances of high impedance inputs.

3.9.2 Thermal considerations

The thermal resistance is determined by the selected SMD package, the PCB layout implementation and the airflow inside the final enclosure of the amplifier.

The TDA8932B/33(B) is available in two different thermally enhanced SMD packages:

- TDA8932BT/33T in SO32 (SOT287-1) package for reflow and wave solder process.
- TDA8932BTW/33BTW in an HTSSOP32 (SOT549-1) package for reflow solder process only.

Thermal resistance SO32 package

The SO32 package has special thermal corner leads, pins 1, 16, 17 and 32, increasing the power capability (reducing the overall $R_{th(j-a)}$) when soldered to a thermal copper plane at V_{SSA} level. The SO package is very suitable for single layer PCB designs or PCB designs with limited space for a thermal plane. Due to the package size the SO32 is able to radiate a significant part of the heat directly into the air (thermal resistance is less depending on the heat transfer via the PCB).

The thermal resistance of a S032 package will range from about 35 K/W to 50 K/W when mounted on a single or two layer PCB (free air natural convection). Mounting a heat sink can further decrease the thermal resistance with another 15 % to 25 %.

The thermal resistance measured at the compact reference PCB (55 mm \times 45 mm) with S032 package can be found in Section 5.3.

Thermal resistance HTSSOP32 package

The HTSSOP32 package has an exposed die-pad that only reduces the overall $R_{th(j-a)}$ significantly when soldered to a thermal copper plane at V_{SSA} level (thermal resistance is strongly depending on the size and the number of copper planes). This makes the HTSSOP package very suitable for multilayer PCB designs with sufficient space for two or three thermal copper planes. When applying three thermal copper planes it is even possible to reach a continuous time output power of 2 \times 25 W without a heat sink.

The thermal resistance of a HTSSOP32 package will range from about 25 K/W to 55 K/W when mounted on a multilayer PCB without heat sink (free air natural convection).

Increasing the area of the thermal copper planes, the number of planes, or the copper thickness will further reduce the thermal resistance $R_{th(j-a)}$ of both packages.

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Airflow inside enclosure

At a set level the airflow inside the enclosure will be limited compared to the situation in free air natural convection. The airflow and other heat sources close to the amplifier will influence the temperature significantly. Therefore it is always recommended (and the responsibility of the set maker) to check the temperature behavior in the final environment of the amplifier.

Remark: The TDA8932B/33(B) amplifier with the thermal foldback feature will never cause audio interruption (audio holes) due to the limited airflow and the limited presence of other heat sources close to the amplifier. Therefore this thermal foldback feature will improve the reliable of the amplifier application under extreme temperature conditions because the device itself will always stay within the Safe Operating Area (SOA).

Thermal resistance

Measured thermal resistance of both the SO32 and the HTSSOP32 reference design can be found in <u>Section 5.3</u>.

Thermal via's

Thermal via's should be applied for an optimum heat flow to other layers of the PCB to reduce the $R_{th(j-a)}$. The thermal via's should be placed close to corner leads and beyond the package for the SO32 package (see PCB layout <u>Section 3.12</u>).

Remark: Do not use via's with web construction, as they will have a high thermal resistance.

Thermal calculations

To estimate the maximum junction temperature, **Equation 22** can be used:

$$T_{j(max)} \approx T_{amb} + R_{th(j-a)} \cdot P \tag{22}$$

Where:

 T_{amb} = ambient temperature (°C)

P = power dissipation in U1 (W) (see Figure 50 or Figure 61, P versus P_0)

 $R_{th(i-a)}$ = thermal resistance junction ambient (K/W)

Example:

Estimation of the junction temperature at P_{rated} (for FTC requirements).

Power dissipation P = 2.5 W (see Figure 47) at P_{rated} = 2 × 15 W in 4 Ω . The estimated junction temperature at T_{amb} = 25 °C and $R_{th(j-a)}$ = 44 K/W, will be $T_{j(max)}$ = 135 °C (approx.) (Equation 22), staying below the TF threshold level of 140 °C.

At a P_{rated} = 2 × 25 W in 4 Ω the TF becomes active. The TF will gradually reduce the gain and therefore reduce the long-term output power. See <u>Section 5.3</u> for the output power as a function of time, when the TF becomes active. The major benefit of the TF feature is that the amplifier is not switched off when it reaches the maximum junction temperature.

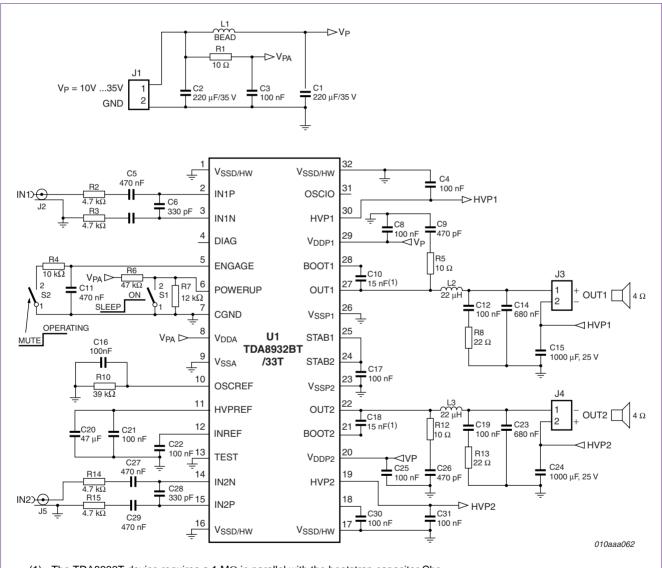
Remark: Lifetime is guaranteed because the TDA8932B/33(B) stays within the safe operating area due to the TF feature.

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Remark: For thermal reliability and/or quality requirements on set level, an average music power of $\frac{1}{4}$ P_{rated} is assumed. This assumption can be made because audio amplifiers are not driven continuously at the rated output power. Taking this into account, shows the major benefit of Class-D as compared to Class-AB. Class-D dissipates less at $\frac{1}{4}$ P_{rated} and that makes it possible to comply easily with the thermal reliability and/or quality regulations with a cheap SO32 or HTSSOP32 package without a heat sink.

3.10 Schematic - revision 3.00



(1) The TDA8933T device requires a 1 $\text{M}\Omega$ in parallel with the bootstrap capacitor Cbo.

Fig 35. Schematic - version 3.00

TDA8932B/33(B) Class-D audio amplifier

3.11 Bill of materials - revision 3.00

Table 8. Bill of materials

ltem	Qty	Reference	Part	Description
1	2	C1, C2	$220~\mu F$ / $35~V$	General purpose 85 °C, Ø 8 mm
2	10	C3, C4, C12, C16, C17, C19, C21, C22, C30, C31	100 nF / 50 V	SMD 0805, X7R
3	5	C5, C7, C11, C27, C29	470 nF / 16 V	SMD 1206, X7R
4	2	C6, C28	330 pF / 16 V	SMD 0805, X7R
5	2	C8, C25	100 nF / 50 V	SMD 1206, X7R
6	2	C26, C9	470 pF / 50 V	SMD 0805, X7R
7	2	C10, C18	15 nF / 16 V	SMD 0805, X7R
8	2	C23, C14	680 nF / 63 V	MKT-02
9	2	C24, C15	1000 μF / 25 V	General purpose 85 °C Ø 12.5 mm
10	1	C20	47 μF / 25 V	General purpose 85 °C Ø 6 mm
11	1	D1	LED	3 mm LED
12	3	J1, J3, J4	Screw terminal	Camden Electronics CTB3551/2
13	2	J2, J5	Cinch	-
14	1	L1	Bead	SMD 1206, 742792115 / Würth Elektronik or BLM41PG600SN1L / Murata
15	2	L3, L2	22 μΗ	11RHBP / Toko A7503CY-220M
16	3	R1, R5, R12	10 R	SMD 1206
17	5	R2, R3, R14, R15, R16	4.7 k	SMD 0805
18	1	R4	10 k	SMD 0805
19	1	R6	47 k	SMD 0805
20	1	R7	12 k	SMD 0805
21	2	R8, R13	22 R	SMD 2512
22	1	R10	39 k	SMD 0805
23	2	S2, S1	PCB switch	090320901 / Secme
24	1	U1	TDA8932BT	SOT287-1 (SO32) / NXP Semiconductors
			TDA8933(B)T	SOT287-1 (SO32) / NXP Semiconductors

3.12 PCB layout - Revision 2

Double-sided PCB (55 mm \times 45 mm) with plated through holes (Ø = 0.6 mm), 35 μm copper and FR4 base material.

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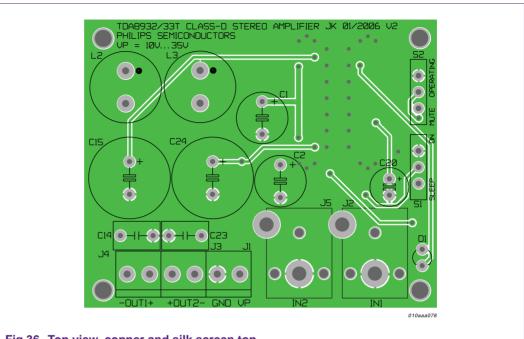


Fig 36. Top view, copper and silk screen top

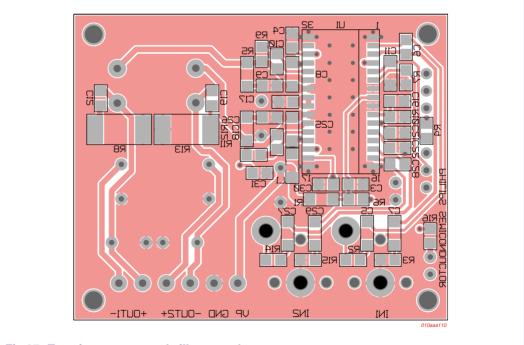


Fig 37. Top view, copper and silk screen bottom

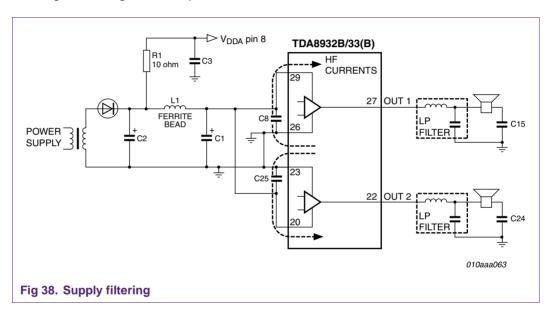
Application note

TDA8932B/33(B) Class-D audio amplifier

4. Power supply

4.1 Supply filtering

A CLC phi filter (C1, L1 and C2) is used to keep the High Frequency (HF) currents locally around the amplifier (see Figure 38). Two 100 nF SMD capacitors (C8 and C25) and an electrolytic buffer capacitor (C1) should be placed close to the amplifier to minimize the area of the HF current loops to avoid emission. The ferrite bead (L1) will avoid the flow of HF currents in (mostly) large supply voltage loops. The analog voltage (V_{DDA}) of the TDA8932B/33(B) requires an RC filter of 10 Ω (R1) and 100 nF (C3) to avoid the HF noise entering the analog controller part of the device.



4.1.1 Lifetime electrolytic capacitor

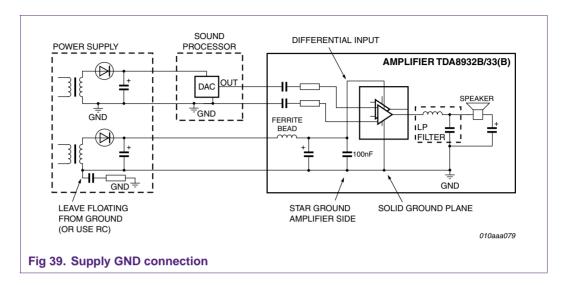
The ambient temperature and the ripple current have the greatest effect on the lifetime of the aluminium electrolytic capacitors. The output power of an amplifier is assumed often to be $\frac{1}{2}$ of the total rated output power. At a power rating of 2×3.75 W ($\frac{1}{2}\times15$ W) the lifetime is not an issue when general-purpose electrolytic capacitors (with a value of at least $220~\mu\text{F}$) are used.

4.2 Supply GND connection

The best practice to avoid any common ground path with the power supply is to leave the supply floating. The power supply should be attached to GND at the amplifier side. The differential input should be grounded at the sound processor and not at the amplifier side.

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TDA8932B/33(B) Class-D audio amplifier



4.3 Low frequency supply pumping effect

A Single Ended (SE) Class-D amplifier will deliver energy back to the supply line (V_P) during the negative part of the audio signal. Because most power supplies are not capable of sinking energy, the supply voltage will increase especially when driving the amplifier at low audio frequencies. This phenomenon is often called the pumping effect.

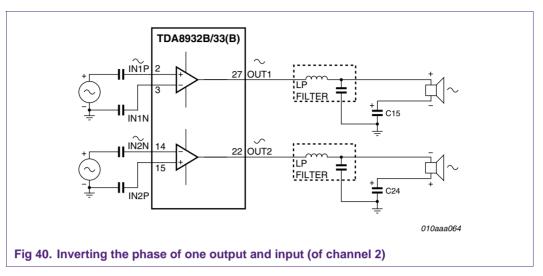
The voltage increase caused by the pumping effect depends on:

- The speaker impedance.
- The supply voltage.
- The audio signal frequency.
- The capacitance value of the supply line.
- The source/sink current of other channels (including the quiescent current of the amplifier).
- The current drawn from other circuits attached to the same supply line.

This voltage increase might trigger the OVP of the audio amplifier and/or cause incorrect control behavior of the regulated power supply.

The most effective way to overcome the pumping effect in a stereo SE application is to apply one of the input signals to the negative input to invert the phase of that particular output (see Figure 40).

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With this method, OUT1 and OUT2 are out of phase to minimize the pumping effect. The inversion of one of the outputs will also halve the peak current drawn from the power supply at a low audio frequency.

Remark: Do not forget to change the polarity of the speaker connection of channel 2 to get the original phase of the signal from the speaker.

4.4 Unregulated or weak power supply

The voltage ripple of an unregulated power supply can be guite significant, due to:

- The output impedance (load regulation).
- A variation on the AC mains (line regulation).
- A cross regulation in a multiple output SMPS.

Therefore, when operating from an asymmetrical supply, this voltage ripple will cause asymmetrical clipping. This might trigger also the UBP (UnBalance Protection) when the voltage ripple exceeds either –20 % or +33 % of the nominal supply voltage (see also Section 2.6.6). Therefore, any unregulated power supply (an auxiliary voltage from either an SMPS or a 50 Hz / 60 Hz transformer) might need some attention to minimize the load, the line and the cross regulation.

The voltage dip during a transient from no load condition to full load condition should be considered. The average supply current in full load for a stereo amplifier can be estimated as follows:

SE:
$$I_{\text{P(avg)}} = \frac{2 \cdot P_o}{\eta_{no} \cdot V_P}$$
 (23)

BTL:
$$I_{P(avg)} = \frac{P_o}{\eta_{po} \cdot V_P}$$
 (24)

Where:

 $P_0 = RMS$ output power per channel (W)

 η_{po} = output power efficiency, audio amplifier

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TDA8932B/33(B) Class-D audio amplifier

 V_P = supply voltage (V) (V_{DDP} - V_{SSP})

Example:

A 2 \times 15 W amplifier at 22 V and 89 % efficiency will draw an average supply current of 1.53 A.

Remark: For either a 50 Hz / 60 Hz transformer or a weak auxiliary supply, it might be worthwhile to consider the use of a symmetrical supply to avoid asymmetrical clipping (early clipping of the positive output voltage).

5. Performance characterization TDA8932B

5.1 Audio characterization SE

5.1.1 Performance figures SE

<u>Table 9</u> shows the measured performance figures of the TDA8932BT two layer reference board (55 mm \times 45 mm) configured in SE configuration.

 V_P = 22 V, R_L = 2 × 4 Ω SE, f_{osc} = 320 kHz, f_i = 1 kHz, T_{amb} = 25 °C unless specified otherwise.

Table 9. Performance figures

Symbol	Parameters	Conditions / notes	Min	Тур	Max	Unit
V_P	supply voltage	operates down to UVP threshold level	10[1]	-	36 <mark>[1]</mark>	V
		operates up to OVP threshold level				
P _{o(RMS)}	RMS output power	Continuous time output power per channel	-	-	-	V
		$R_L = 4 \Omega$	-	-	-	
		THD+N = 10 %	-	15.3	-	W
		THD+N = 0.5 %	-	12.1	-	V W W - W W W W W M dB
		$R_L = 8 \Omega, V_P = 30 V$	-	-	-	-
		THD+N = 10 %	-	15.5	-	W
		THD+N = 0.5 %	-	12.3	-	W
		short time output power	-	-	-	-
		$R_L = 4 \Omega$, $VP = 29 V$	-	-	-	-
		THD+N = 10 %	-	26.5	-	W
		THD+N = 0.5 %	-	21.1	-	W
THD+N	total harmonic distortion-plus-noise	P _o = 1 W, AES17 brick wall filter 20 kHz	-	-	-	-
		$R_L = 4 \Omega$	-	0.015	-	%
		$R_L = 8 \Omega, V_P = 30 V$	-	0.01	-	%
ηρο	output power efficiency	P _o = 15 W	-	-	-	-
•		$R_L = 4 \Omega$	-	92	-	%
		$R_L = 8 \Omega, V_P = 30 V$	-	93	-	%
G _{v(cl)}	closed-loop voltage gain	V_i = 100 m V_{RMS} , 1 kHz, R_i = 4.7 kΩ, no load	-	29.2	-	dB
V _{i(sens)}	input sensitivity voltage	$P_{\text{rated}} = 2 \times 15 \text{ W}$	-	305	-	mV _{RM} s

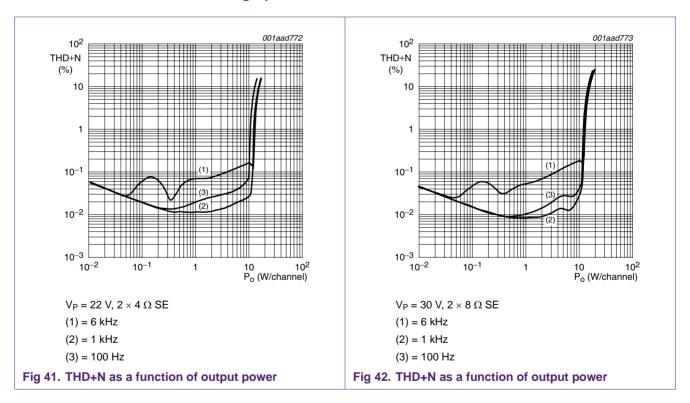
TDA8932B/33(B) Class-D audio amplifier

Table 9. Performance figures ... continued

Symbol	Parameters	Conditions / notes	Min	Тур	Max	Unit
$V_{n(o)}$	noise output voltage	MUTE mode	-	70	-	μV
		OPERATING mode, inputs shorted at INP, INN	-	100	-	μV
S/N	Signal to Noise ratio	unweighted, w.r.t. $V_O = 7.8 V_{RMS}$	-	98	-	dB
В	bandwidth	± 3 dB, C15 = C24 = 1000 μF	-	40 - 45,000	-	Hz
SVRR	supply voltage ripple rejection	R_L = 4 Ω,V_{ripple} = 500 mV $_{RMS},$ 100 Hz, inputs shorted	-	62	-	dB
		R_L = 8 Ω , V_{ripple} = 500 m V_{RMS} , 100 Hz, inputs shorted	-	60	-	dB
$\alpha_{\sf cs}$	channel separation	P _o = 1 W, 1 kHz	-	80	-	dB
I _P	supply current	total application; SLEEP mode, no load	-	680	-	μΑ
Iq	quiescent current	total application; MUTE / OPERATING mode	-	53	-	mA

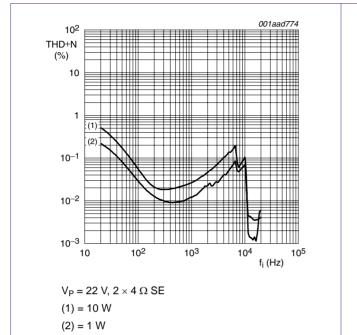
^[1] It is not recommended to operate the IC at the supply boundaries (10 V or 36 V) unless the supply is regulated well.

5.1.2 Performance graphs SE



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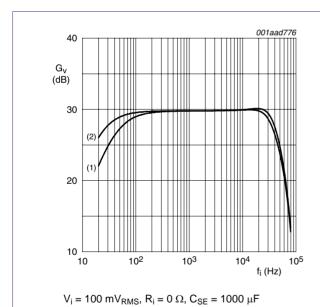


001aad775 10² THD+N (%) 10 1 (1) 10-1 10-2 10⁻³ 102 103 10⁵ 10 f_i (Hz) $V_P = 30 \text{ V}, 2 \times 8 \Omega \text{ SE}$ (1) = 10 W(2) = 1 W

001aad777

Fig 43. THD+N as a function of frequency





(1) $2 \times 4 \Omega$ SE @ $V_P = 22 V$

(2) $2 \times 8 \Omega SE @ V_P = 30 V$

Application note



SVRR

(dB)

-40

-60

-80

 $V_{ripple} = 500 \text{ mV}_{RMS} \text{ w.r.t. GND, shorted input}$

10³

10⁴

10⁵

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f_i (Hz)

 $R_i = 0 \Omega$

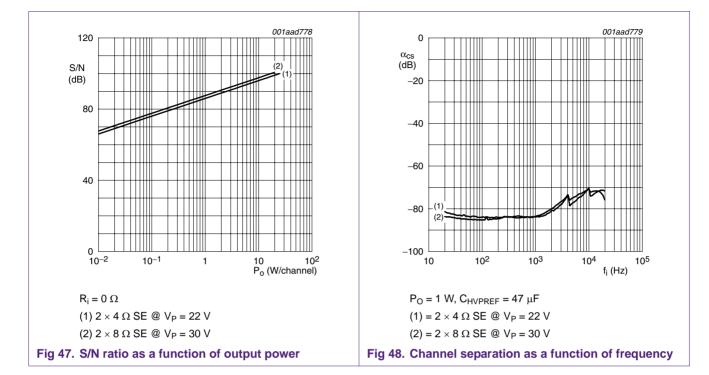
(1) = $2 \times 4 \Omega SE @ V_P = 22 V$

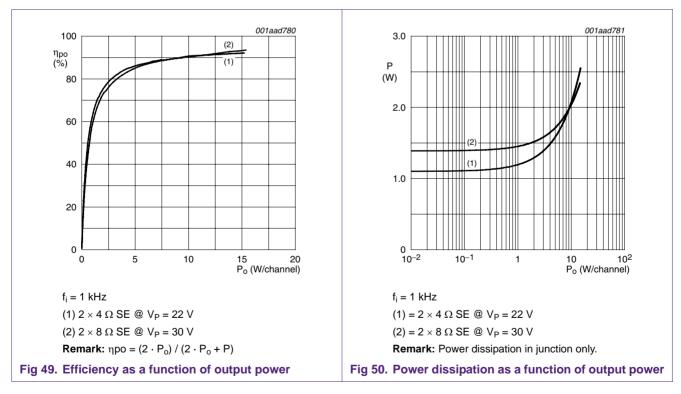
10²

(2) = $2 \times 8 \Omega$ SE @ $V_P = 30 V$

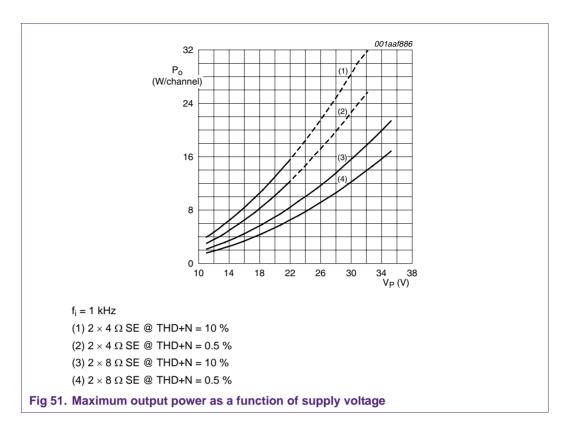
Fig 45. Gain as a function of frequency Fig 46. SVRR as a function of frequency

TDA8932B/33(B) Class-D audio amplifier





TDA8932B/33(B) Class-D audio amplifier



5.2 Audio characterization BTL

5.2.1 Performance figures BTL

<u>Table 10</u> shows the measured performance figures of the TDA8932BT two layer reference board (55 mm \times 45 mm) configured in BTL configuration.

 V_P = 22 V, R_L = 8 Ω BTL, f_{osc} = 320 kHz, f_i = 1 kHz, T_{amb} = 25 °C unless specified otherwise.

Table 10. Performance figures

Parameter	Conditions/notes	Min	Тур	Max	Unit
supply voltage	operates down to UVP threshold level; operates up to OVP threshold level	10[1]	-	36[1]	V
RMS output power	$R_L = 8 \Omega$	-	-	-	
	THD+N = 10 %	-	32.1	-	W
	THD+N = 0.5 %	-	25.7	-	W
	$R_L = 4 \Omega$; $V_P = 12 V$	-	-	-	-
	THD+N = 10 %	-	17.2	-	W
	THD+N = 0.5 %	-	13.2	-	W
total harmonic distortion-plus-noise	P _o = 1 W, AES17 brick wall filter 20 kHz	-	-	-	-
	$R_L = 8 \Omega$	-	0.007	-	%
	$R_L = 4 \Omega$, $VP = 12 V$	-	0.02	-	%
output power efficiency	$P_0 = 15 \text{ W}, V_P = 22 \text{ V}, R_L = 8 \Omega$	-	90	-	%
	P_{0} = 30 W, V_{P} = 12 V, R_{L} = 4 Ω	-	92	-	%
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	supply voltage RMS output power total harmonic distortion-plus-noise	supply voltage $ \begin{array}{ll} \text{supply voltage} & \text{operates down to UVP threshold level;} \\ \text{RMS output power} & R_L = 8 \ \Omega \\ \hline & T\text{HD+N} = 10 \ \% \\ \hline & T\text{HD+N} = 0.5 \ \% \\ \hline & R_L = 4 \ \Omega; \ V_P = 12 \ V \\ \hline & T\text{HD+N} = 10 \ \% \\ \hline & T\text{HD+N} = 0.5 \ \% \\ \hline \text{total harmonic} & D_0 = 1 \ W, \ AES17 \ brick \ wall \ filter \ 20 \ kHz \\ \hline & R_L = 8 \ \Omega \\ \hline & R_L = 4 \ \Omega, \ VP = 12 \ V \\ \hline \text{output power efficiency} & P_0 = 15 \ W, \ V_P = 22 \ V, \ R_L = 8 \ \Omega \\ \hline \end{array} $	$\begin{array}{llllllllllllllllllllllllllllllllllll$	$ \begin{array}{c} \text{supply voltage} & \text{operates down to UVP threshold level}; \\ \text{operates up to OVP threshold level} \\ \hline \\ \text{RMS output power} & \begin{array}{c} R_L = 8 \ \Omega \\ \hline \text{THD+N} = 10 \ \% \\ \hline \text{THD+N} = 0.5 \ \% \\ \hline R_L = 4 \ \Omega; \ V_P = 12 \ V \\ \hline \text{THD+N} = 10 \ \% \\ \hline \text{THD+N} = 0.5 \ \% \\ \hline \end{array} & \begin{array}{c} - \ 25.7 \\ \hline R_L = 4 \ \Omega; \ V_P = 12 \ V \\ \hline \end{array} & \begin{array}{c} - \ 17.2 \\ \hline \text{THD+N} = 0.5 \ \% \\ \hline \end{array} & \begin{array}{c} - \ 13.2 \\ \hline \end{array} \\ \hline \end{array} \\ \begin{array}{c} \text{total harmonic distortion-plus-noise} \\ R_L = 8 \ \Omega \\ \hline R_L = 4 \ \Omega, \ VP = 12 \ V \\ \hline \end{array} & \begin{array}{c} - \ 0.007 \\ \hline \end{array} \\ \hline \end{array} \\ \begin{array}{c} \text{Output power efficiency} \\ \end{array} & \begin{array}{c} P_0 = 15 \ W, \ V_P = 22 \ V, \ R_L = 8 \ \Omega \\ \hline \end{array} & \begin{array}{c} - \ 90 \\ \hline \end{array}$	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$

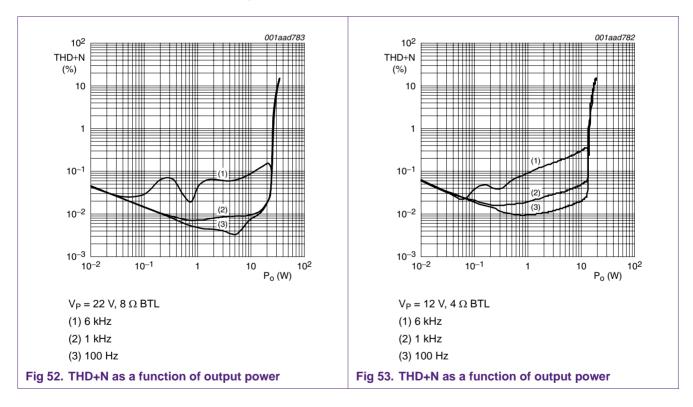
TDA8932B/33(B) Class-D audio amplifier

Table 10. Performance figures ...continued

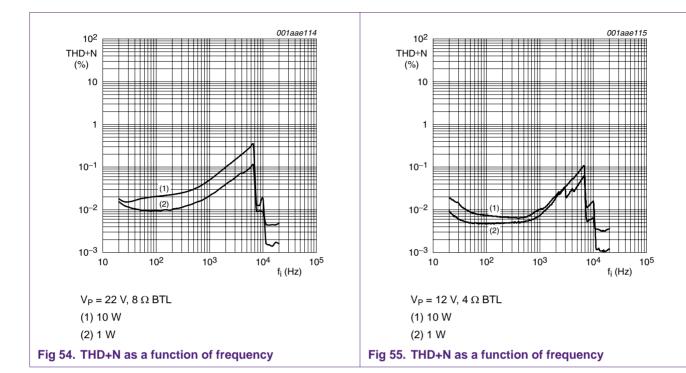
Symbol	Parameter	Conditions/notes	Min	Тур	Max	Unit
G _{v(cl)}	closed-loop voltage gain	V_i = 100 m V_{RMS} , 1 kHz, R_i = 4.7 k Ω , no load	-	35.2	-	dB
V _{i(sens)}	input sensitivity voltage	$P_{rated} = 30 \text{ W}, R_i = 4.7 \text{ k}\Omega$	-	305	-	${\rm mV}_{\rm rms}$
$V_{n(o)}$	noise output voltage	MUTE mode	-	25	-	μV
		OPERATING mode, inputs shorted at INP, INN	-	100	-	μV
S/N	signal-to-noise ratio	unweighted, in relation to $V_O = 15.5 V_{RMS}$	-	104	-	dB
В	bandwidth	±3 dB	0 to 4	15,000		Hz
SVRR	supply voltage ripple rejection	R_L = 8 W, V_{ripple} = 500 m V_{RMS} , 100 Hz, inputs shorted	-	77	-	dB
		$R_L = 4 \text{ W}$, $V_{ripple} = 500 \text{ mV}_{RMS}$, 100 Hz, inputs shorted	-	77	-	dB
I _P	supply current	SLEEP mode, no load	-	680	-	μΑ
Iq	quiescent current	MUTE / OPERATING mode	-	53	-	mA

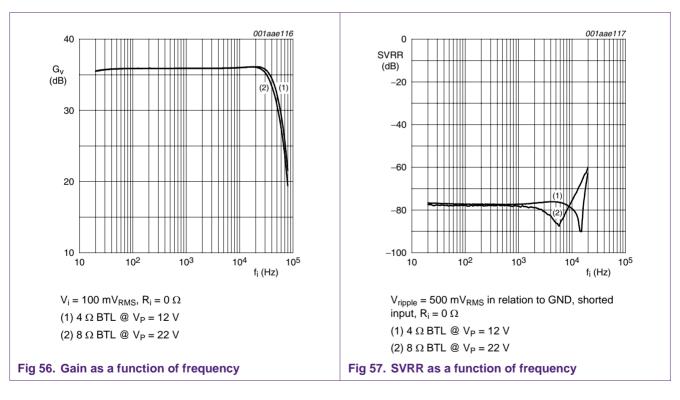
^[1] It is not recommended to operate the IC at the supply boundaries (10 V or 36 V) unless the supply is regulated well.

5.2.2 Performance graphs BTL

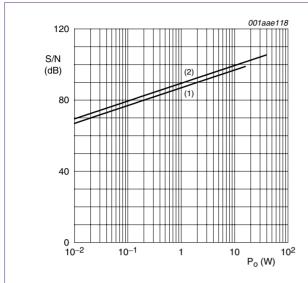


TDA8932B/33(B) Class-D audio amplifier





TDA8932B/33(B) Class-D audio amplifier

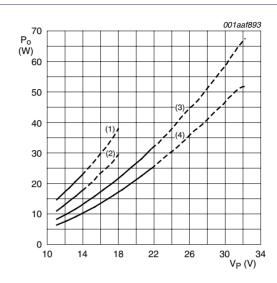


 $R_i = 0 \Omega$

(1) $4 \Omega BTL @ V_P = 12 V$

(2) 8 Ω BTL @ V_P = 22 V

Fig 58. S/N ratio as a function of output power



 $f_i = 1 \text{ kHz}$

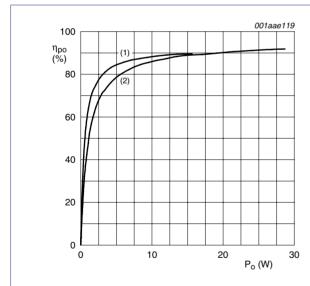
(1) 4 Ω BTL @ THD+N = 10 %

(2) 4 Ω BTL @ THD+N = 0.5 %

(3) 8 Ω BTL @ THD+N = 10 %

(4) 8 Ω BTL @ THD+N = 0.5 %

Fig 59. Maximum output power as a function of supply voltage



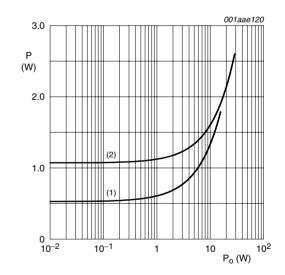
 $f_i = 1 \text{ kHz}$

(1) $4 \Omega BTL @ V_P = 12 V$

(2) 8 Ω BTL @ V_P = 22 V

Remark: $\eta_{po} = (P_o) / (P_o + P)$

Fig 60. Efficiency as a function of output power



 $f_i = 1 \text{ kHz}$

(1) 4 Ω BTL @ V_P = 12 V

(2) 8 Ω BTL @ V_P = 22 V

Remark: Power dissipation in junction only

Fig 61. Power dissipation as a function of output power

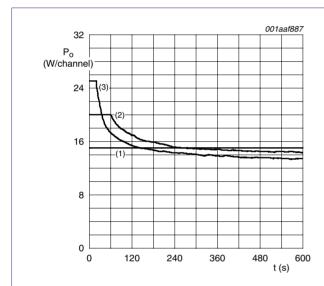
TDA8932B/33(B) Class-D audio amplifier

5.3 Thermal characterization

The measured thermal resistance of the reference design with an SO32 package, a double-sided FR4 PCB (55 mm \times 45 mm) and 35 μm copper, is equal to 44 K/W (free air and natural convection).

When the junction temperature reaches the threshold level of the Thermal Foldback (140 °C to 150 °C), it starts to reduce gradually the output power so the maximum temperature will stay always within the Safe Operating Area.

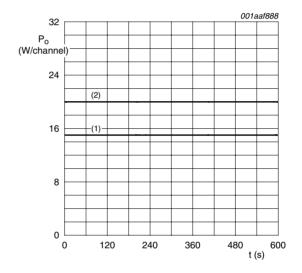
<u>Figure 62</u> and <u>Figure 63</u> show the TDA8932BT (S032) output power as a function of time at different supply voltages. The total output power of the device is $2 \times P_0$, because the measurement is performed at SE configuration.



 R_L = 2 \times 4 Ω SE; f_i = 1 kHz; 2 layer SO32 application board (55 mm \times 45 mm) without heat sink.

- (1) $V_P = 22 V$
- (2) $V_P = 26 \text{ V}$
- (3) $V_P = 29 V$

Fig 62. SE output power as a function of time



 $R_L = 2 \times 8~\Omega$ SE; $f_i = 1~kHz$; 2 layer SO32 application board (55 mm \times 45 mm) without heat sink.

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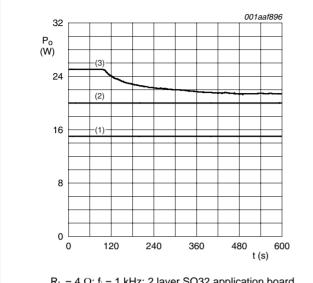
- (1) $V_P = 30 \text{ V}$
- (2) $V_P = 34 V$

Fig 63. SE output power as a function of time

<u>Figure 64</u> and <u>Figure 65</u> show the TDA8932BT output power as a function of time at different supply voltages. Total output power of the device is $1 \times P_0$ because the measurement is performed at BTL configuration.

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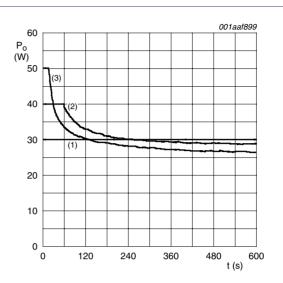
TDA8932B/33(B) Class-D audio amplifier



 $R_L=4~\Omega;\, f_i=1$ kHz; 2 layer SO32 application board (55 mm \times 45 mm) without heat sink.

- (1) $V_P = 12 V$
- (2) $V_P = 13.5 \text{ V}$
- (3) $V_P = 15 V$

Fig 64. BTL output power as a function of time



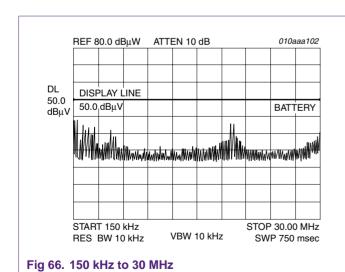
 $R_L=8~\Omega;~f_i=1$ kHz; 2 layer SO32 application board (55 mm \times 45 mm) without heat sink.

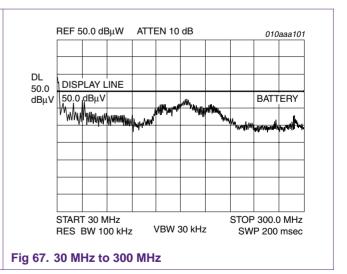
- (1) $V_P = 22 V$
- (2) $V_P = 26 \text{ V}$
- (3) VP = 29 V

Fig 65. BTL output power as a function of time

5.4 EMI characterization (FCC)

The TDA8932B/33(B) reference design can comply easily with the FCC radiated emissions standards with 1 m of cable attached to all the I/Os. The spectrum analyzer is set at MAX hold and the output power is 2 \times 1/8 P_{rated} .





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6. Legal information

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TDA8932B/33(B) Class-D audio amplifier

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